

WIDEBAND, LOW-DISTORTION FULLY DIFFERENTIAL AMPLIFIERS

FEATURES

- Controlled Baseline
- One Assembly/Test Site, One Fabrication Site
- Enhanced Diminishing Manufacturing Sources (DMS) Support
- Enhanced Product-Change Notification
- Qualification Pedigree⁽¹⁾
- Fully Differential Architecture
- Bandwidth: 370 MHz
- Slew Rate: 2800 V/ μ s
- IMD₃: -95 dBc at 30 MHz
- OIP₃: 51 dBm at 30 MHz
- Output Common-Mode Control
- Wide Power Supply Voltage Range: 5 V, \pm 5 V, 12 V, 15 V
- Centered Input Common-Mode Range
- Evaluation Module Available

⁽¹⁾ Component qualification in accordance with JEDEC and industry standards to ensure reliable operation over an extended temperature range. This includes, but is not limited to, Highly Accelerated Stress Test (HAST) or biased 85/85, temperature cycle, autoclave or unbiased HAST, electromigration, bond intermetallic life, and mold compound life.

DESCRIPTION

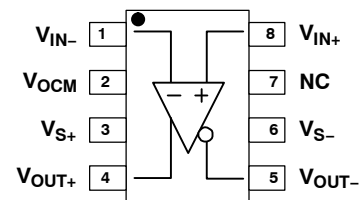
The THS4503 is a high-performance fully differential amplifier from Texas Instruments. The THS4503, without power-down capability, set new performance standards for fully differential amplifiers with unsurpassed linearity, supporting 14-bit operation through 40 MHz. Package options include the 8-pin MSOP with PowerPAD™ for a smaller footprint, enhanced ac performance, and improved thermal dissipation capability.

WARNING:

The THS4503 may have low-level oscillation when the die temperature (also known as the junction temperature) exceeds 60°C. These devices are not recommended for new designs where the die temperature is expected to exceed 60°C. For more information, see Maximum Die Temperature to Oscillation.

APPLICATIONS

- High Linearity Analog-to-Digital Converter Preamplifier
- Wireless Communication Receiver Chains
- Single-Ended to Differential Conversion
- Differential Line Driver
- Active Filtering of Differential Signals



RELATED DEVICES

DEVICE ⁽¹⁾	DESCRIPTION
THS4500/1	370 MHz, 2800 V/ μ s, V_{ICR} Includes V_{S-}
THS4502/3	370 MHz, 2800 V/ μ s, Centered V_{ICR}
THS4120/1	3.3 V, 100 MHz, 43 V/ μ s, 3.7 nV/ \sqrt Hz
THS4130/1	\pm 15 V, 150 MHz, 51 V/ μ s, 1.3 nV/ \sqrt Hz
THS4140/1	\pm 15 V, 160 MHz, 450 V/ μ s, 6.5 nV/ \sqrt Hz
THS4150/1	\pm 15 V, 150 MHz, 650 V/ μ s, 7.6 nV/ \sqrt Hz

⁽¹⁾ Even numbered devices feature power-down capability



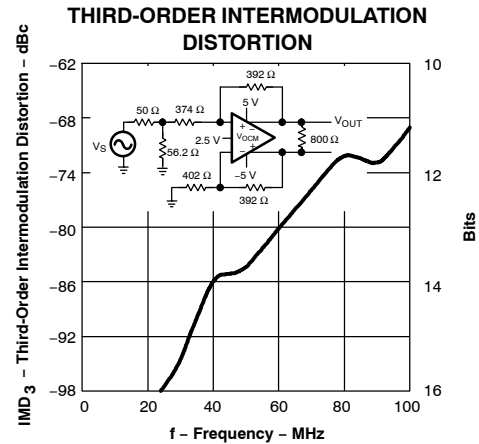
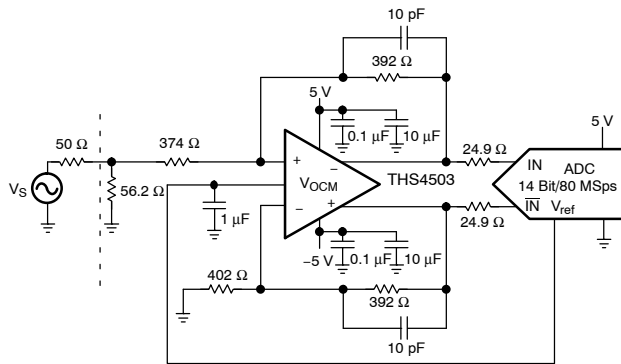
Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

PowerPAD is a trademark of Texas Instruments.

THS4503-EP

SGLS291A – APRIL 2005 – JANUARY 2012

APPLICATION CIRCUIT DIAGRAM



ABSOLUTE MAXIMUM RATINGS

 over operating free-air temperature range unless otherwise noted⁽¹⁾

	UNIT	
Supply voltage, V_S	16.5 V	
Input voltage, V_I	$\pm V_S$	
Output current, I_O ⁽²⁾	150 mA	
Differential input voltage, V_{ID}	4 V	
Continuous power dissipation	See Dissipation Rating Table	
Maximum junction temperature, T_J ⁽³⁾	150°C	
Maximum junction temperature, continuous operation, long term reliability T_J ⁽⁴⁾	125°C	
Maximum junction temperature, to prevent oscillation T_J ⁽⁵⁾	60°C	
Operating free-air temperature range, T_A	-55°C to 60°C	
Storage temperature range, T_{stg}	-65°C to 150°C	
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	300°C	
ESD ratings:	HBM	4000 V
	CDM	2000 V
	MM	100 V

- Stresses above these ratings may cause permanent damage. Exposure to absolute maximum conditions for extended periods may degrade device reliability. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those specified is not implied.
- The THS450x may incorporate a PowerPAD on the underside of the chip. This acts as a heatsink and must be connected to a thermally dissipative plane for proper power dissipation. Failure to do so may result in exceeding the maximum junction temperature which could permanently damage the device. See Texas Instruments technical brief SLMA002 for more information about utilizing the PowerPAD thermally enhanced package.
- The absolute maximum temperature under any condition is limited by the constraints of the silicon process.
- Long-term high-temperature storage and/or extended use at maximum recommended operating conditions may result in a reduction of overall device life. See Figure 1 for additional information on thermal derating.
- See Maximum Die Temperature to Prevent Oscillation section in the Application Information of this data sheet.



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

PACKAGE DISSIPATION RATINGS

PACKAGE	θ_{JC} (°C/W)	θ_{JA} ⁽¹⁾ (°C/W)
DGN (8 pin)	4.7	58.4

⁽¹⁾ This data was taken using the JEDEC standard High-K test PCB.

RECOMMENDED OPERATING CONDITIONS

		MIN	NOM	MAX	UNIT
Supply voltage	Dual supply		± 5	± 7.5	V
	Single supply	4.5	5	15	
Operating free-air temperature, T_A		-55		60	°C

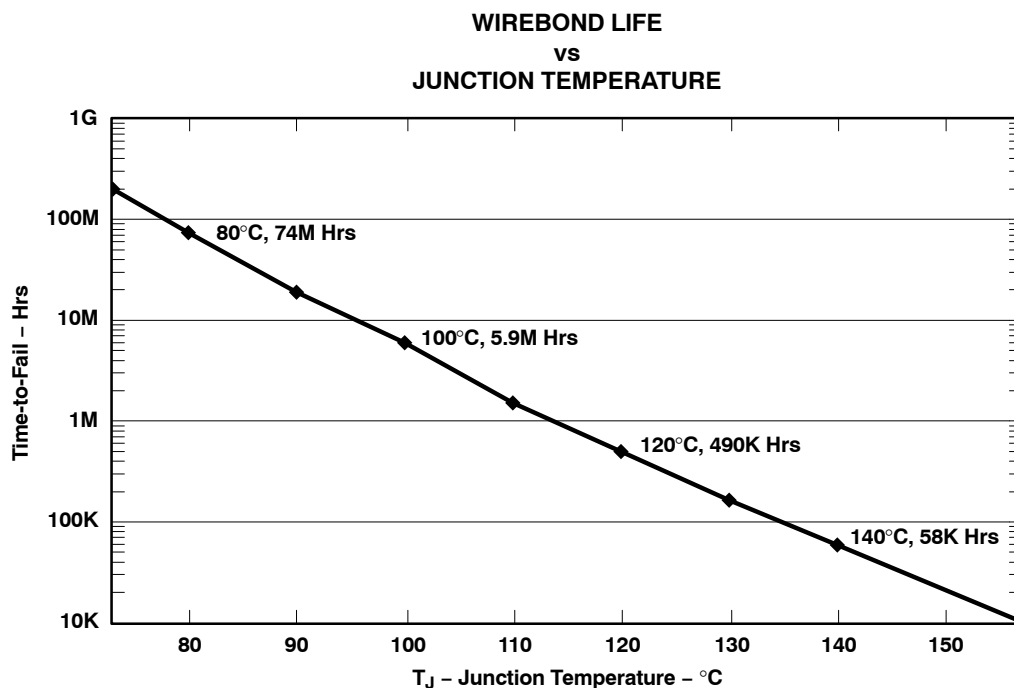


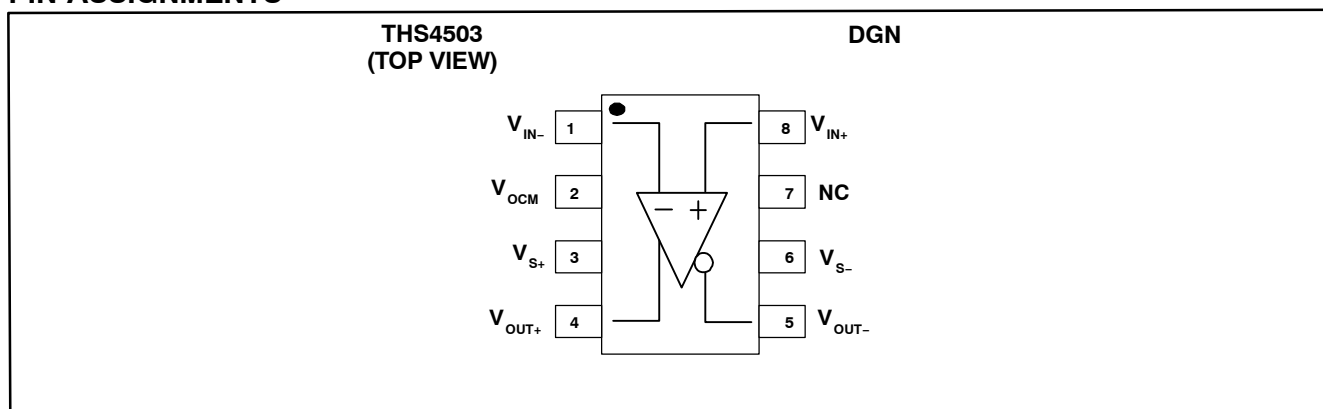
Figure 1. EME-G600 Estimated Wirebond Life

PACKAGE/ORDERING INFORMATION

TEMPERATURE	ORDERABLE PACKAGE AND NUMBER	
	PLASTIC MSOP ⁽¹⁾ PowerPAD	
	(DGN)	SYMBOL
-55°C to 60°C	THS4503MDGNREP	BLB

⁽¹⁾ All packages are available taped and reeled. The R suffix standard quantity is 2500.

PIN ASSIGNMENTS



THS4503-EP

SGLS291A – APRIL 2005 – JANUARY 2012

ELECTRICAL CHARACTERISTICS $V_S = \pm 5\text{ V}$
 $R_f = R_g = 1\text{ k}\Omega$, $R_L = 399\ \Omega$, $G = +1$, Single-ended input unless otherwise noted

PARAMETER	TEST CONDITIONS	THS4503				
		TYP	OVER TEMPERATURE ⁽¹⁾			MIN/ TYP/ MAX
		25°C	25°C	-55°C TO 60°C	UNITS	
AC PERFORMANCE						
Small-signal bandwidth	$G = +1$, $P_{IN} = -20\text{ dBm}$, $R_f = 392\ \Omega$	370			MHz	Typ
	$G = +2$, $P_{IN} = -30\text{ dBm}$, $R_f = 1\text{ k}\Omega$	175				
	$G = +5$, $P_{IN} = -30\text{ dBm}$, $R_f = 1.3\text{ k}\Omega$	70				
	$G = +10$, $P_{IN} = -30\text{ dBm}$, $R_f = 1.3\text{ k}\Omega$	30				
Gain-bandwidth product	$G > +10$	300			MHz	Typ
Bandwidth for 0.1dB flatness	$P_{IN} = -20\text{ dBm}$	150			MHz	Typ
Large-signal bandwidth	$V_P = 2\text{ V}$	220			MHz	Typ
Slew rate	4 V_{PP} Step	2800			V/ μ s	Typ
Rise time	2 V_{PP} Step	0.8			ns	Typ
Fall time	2 V_{PP} Step	0.6			ns	Typ
Settling time to 0.01%	$V_O = 4\ V_{PP}$	8.3			ns	Typ
Settling time to 0.1%	$V_O = 4\ V_{PP}$	6.3			ns	Typ
Harmonic distortion	$G = +1$, $V_O = 2\ V_{PP}$					Typ
2 nd harmonic	$f = 8\text{ MHz}$	-83			dBc	Typ
	$f = 30\text{ MHz}$	-74			dBc	Typ
3 rd harmonic	$f = 8\text{ MHz}$	-97			dBc	Typ
	$f = 30\text{ MHz}$	-78			dBc	Typ
Third-order intermodulation distortion	$V_O = 2V_{PP}$, $f_c = 30\text{ MHz}$, $R_f = 392\ \Omega$, 200-kHz tone spacing	-94			dBc	Typ
Third-order output intercept point	$f_c = 30\text{ MHz}$, $R_f = 392\ \Omega$, Referenced to 50 Ω	52			dBm	Typ
Input voltage noise	$f > 1\text{ MHz}$	6.8			nV/ $\sqrt{\text{Hz}}$	Typ
Input current noise	$f > 100\text{ kHz}$	1.7			pA/ $\sqrt{\text{Hz}}$	Typ
Overdrive recovery time	Overdrive = 5.5 V	75			ns	Typ
DC PERFORMANCE						
Open-loop voltage gain		55	52	48	dB	Min
Input offset voltage	$V_{OD} = \pm 4\text{ V}$, $V_{OCM} = 0\text{ V}$	-1	± 6	± 7	mV	Max
Average offset voltage drift				± 10	$\mu\text{V}/^\circ\text{C}$	Typ
Input bias current		4	4.6	5.4	μA	Max
Average bias current drift				± 10	nA/ $^\circ\text{C}$	Typ
Input offset current		0.5	1	2	μA	Max
Average offset current drift				± 40	nA/ $^\circ\text{C}$	Typ
INPUT						
Common-mode input range		± 4.0	± 3.7	± 3.4	V	Min
Common-mode rejection ratio		80	74	70	dB	Min
Input impedance	$V_{ICM} = \pm 0.5\text{ V}$, $V_{OCM} = 0\text{ V}$	$10^7 \parallel 1$			$\Omega \parallel \text{pF}$	Typ
OUTPUT						
Differential output voltage swing	$R_L = 399\ \Omega$	± 8	± 7.6	± 7.4	V	Min
Differential output current drive	$R_L = 20\ \Omega$	120	110	100	mA	Min
Output balance error	$P_{IN} = -20\text{ dBm}$, $f = 100\text{ kHz}$	-58			dB	Typ
Closed-loop output impedance (single-ended)	$f = 1\text{ MHz}$	0.1			Ω	Typ

ELECTRICAL CHARACTERISTICS $V_S = \pm 5\text{ V}$

$R_f = R_g = 1\text{ k}\Omega$, $R_L = 399\ \Omega$, $G = +1$, Single-ended input unless otherwise noted

PARAMETER	TEST CONDITIONS	THS4503				MIN/ TYP/ MAX
		TYP	OVER TEMPERATURE ⁽¹⁾		UNITS	
		25°C	25°C	-55°C TO 60°C		
OUTPUT COMMON-MODE VOLTAGE CONTROL						
Small-signal bandwidth	$R_L = 400\ \Omega$	180			MHz	Typ
Slew rate	$2\ V_{PP}$ step	87			V/ μ s	Typ
Minimum gain		1	0.98	0.98	V/V	Min
Maximum gain		1	1.02	1.02	V/V	Max
Common-mode offset voltage		+2	± 7.5	± 9.9	mV	Max
Input bias current	$V_{OCM} = 2.5\text{ V}$	100	150	170	μ A	Max
Input voltage range		± 4	± 3.7	± 3.4	V	Min
Input impedance		$25\ \parallel\ 1$			k $\Omega\ \parallel\ \mu$ F	Typ
Maximum default voltage	V_{OCM} left floating	0	0.05	0.1	V	Max
Minimum default voltage	V_{OCM} left floating	0	-0.05	-0.1	V	Min
POWER SUPPLY						
Specified operating voltage		± 5	± 7.5	± 7.5	V	Max
Maximum quiescent current		23	28	34	mA	Max
Minimum quiescent current		23	16	10	mA	Min
Power supply rejection (\pm PSRR)	$V_{S+} = 4\text{ V to } 5\text{ V}$, $V_{S-} = -5\text{ V to } -4\text{ V}$	80	76	70	dB	Min

⁽¹⁾ See Maximum Die Temperature to Prevent Oscillation section in the Application Information of this data sheet.

ELECTRICAL CHARACTERISTICS $V_S = 5\text{ V}$

$R_f = R_g = 1\text{ k}\Omega$, $R_L = 399\ \Omega$, $G = +1$, Single-ended input unless otherwise noted

PARAMETER	TEST CONDITIONS	THS4503				MIN / TYP / MAX
		TYP	OVER TEMPERATURE		UNITS	
		25°C	25°C	-55°C TO 60°C		
AC PERFORMANCE						
Small-signal bandwidth	$G = +1$, $P_{IN} = -20\text{ dBm}$, $R_f = 392\ \Omega$	320			MHz	Typ
	$G = +2$, $P_{IN} = -30\text{ dBm}$, $R_f = 1\text{ k}\Omega$	160				
	$G = +5$, $P_{IN} = -30\text{ dBm}$, $R_f = 1.3\text{ k}\Omega$	60				
	$G = +10$, $P_{IN} = -30\text{ dBm}$, $R_f = 1.3\text{ k}\Omega$	30				
Gain-bandwidth product	$G > +10$	300			MHz	Typ
Bandwidth for 0.1-dB flatness	$P_{IN} = -20\text{ dBm}$	180			MHz	Typ
Large-signal bandwidth	$V_P = 1\text{ V}$	200			MHz	Typ
Slew rate	$2\ V_{PP}$ Step	1300			V/ μ s	Typ
Rise time	$2\ V_{PP}$ Step	0.6			ns	Typ
Fall time	$2\ V_{PP}$ Step	0.8			ns	Typ
Settling time to 0.01%	$V_O = 2\text{ V}$ Step	13.1			ns	Typ
Settling time to 0.1%	$V_O = 2\text{ V}$ Step	8.3			ns	Typ
Harmonic distortion	$V_O = 2\ V_{PP}$					Typ
2 nd harmonic	$f = 8\text{ MHz}$,	-81			dBc	Typ
	$f = 30\text{ MHz}$	-60				
3 rd harmonic	$f = 8\text{ MHz}$	-74			dBc	Typ
	$f = 30\text{ MHz}$	-62				
Input voltage noise	$f > 1\text{ MHz}$	6.8			nV/ $\sqrt{\text{Hz}}$	Typ
Input current noise	$f > 100\text{ kHz}$	1.6			pA/ $\sqrt{\text{Hz}}$	Typ
Overdrive recovery time	Overdrive = 5.5 V	75			ns	Typ

THS4503-EP

SGLS291A – APRIL 2005 – JANUARY 2012

ELECTRICAL CHARACTERISTICS $V_S = 5\text{ V}$

 $R_f = R_g = 1\text{ k}\Omega$, $R_L = 399\ \Omega$, $G = +1$, Single-ended input unless otherwise noted

PARAMETER	TEST CONDITIONS	THS4503				
		TYP	OVER TEMPERATURE			MIN / TYP / MAX
		25°C	25°C	-55°C TO 60°C	UNITS	
DC PERFORMANCE						
Open-loop voltage gain		54	51	48	dB	Min
Input offset voltage	$V_{OD} = \pm 1\text{ V}$, $V_{OCM} = 2.5\text{ V}$	-0.6	± 5	± 6.5	mV	Max
Average offset voltage drift				± 10	$\mu\text{V}/^\circ\text{C}$	Typ
Input bias current		4	4.6	5.2	μA	Max
Average bias current drift				± 10	nA/ $^\circ\text{C}$	Typ
Input offset current		0.5	0.7	1.2	μA	Max
Average offset current drift				± 20	nA/ $^\circ\text{C}$	Typ
INPUT						
Common-mode input range		1 / 4	1.3 / 3.7	1.6 / 3.4	V	Min
Common-mode rejection ratio		80	74	60	dB	Min
Input impedance	$V_{ICM} = 2.25\text{ V to } 2.75\text{ V}$, $V_{OCM} = 2.5\text{ V}$	$10^7 \parallel 1$			$\Omega \parallel \text{pF}$	Typ
OUTPUT						
Differential output voltage swing	$R_L = 399\ \Omega$, Referenced to 2.5 V	± 3.3	± 2.8	± 2.6	V	Min
Output current drive	$R_L = 20\ \Omega$	100	90	80	mA	Min
Output balance error	$P_{IN} = -20\text{ dBm}$, $f = 100\text{ kHz}$	-58			dB	Typ
Closed-loop output impedance (single ended)	$f = 1\text{ MHz}$	0.1			Ω	Typ
OUTPUT COMMON-MODE VOLTAGE CONTROL						
Small-signal bandwidth	$R_L = 400\ \Omega$	180			MHz	Typ
Slew rate	2 V_{PP} Step	80			V/ μs	Typ
Minimum gain		1	0.98	0.98	V/V	Min
Maximum gain		1	1.02	1.02	V/V	Max
Common-mode offset voltage		2	± 6.7	± 9.2	mV	Max
Input bias current	$V_{OCM} = 2.5\text{ V}$	1	2	3	μA	Max
Input voltage range		1/4	1.2/3.8	1.3/3.7	V	Min
Input impedance		$25 \parallel 1$			k $\Omega \parallel \text{pF}$	Typ
Maximum default voltage	V_{OCM} left floating	2.5	2.55	2.6	V	Max
Minimum default voltage	V_{OCM} left floating	2.5	2.45	2.4	V	Min
POWER SUPPLY						
Specified operating voltage		5	15	15	V	Max
Maximum quiescent current		20	25	31	mA	Max
Minimum quiescent current		20	15	8	mA	Min
Power supply rejection (+PSRR)	$V_{S+} = 4.5\text{ V to } 5.5\text{ V}$	75	72	66	dB	Min

TYPICAL CHARACTERISTICS
Table of Graphs (± 5 V)

	FIGURE
Small signal unity gain frequency response	1
Small signal frequency response	2
0.1 dB gain flatness frequency response	3
Harmonic distortion (single-ended input to differential output) vs Frequency	4, 6, 12, 14
Harmonic distortion (differential input to differential output) vs Frequency	5, 7, 13, 15
Harmonic distortion (single-ended input to differential output) vs Output voltage swing	8, 10, 16, 18
Harmonic distortion (differential input to differential output) vs Output voltage swing	9, 11, 17, 19
Harmonic distortion (single-ended input to differential output) vs Load resistance	20
Harmonic distortion (differential input to differential output) vs Load resistance	21
Third order intermodulation distortion (single-ended input to differential output) vs Frequency	22
Third order output intercept point vs Frequency	23
Slew rate vs Differential output voltage step	24
Settling time	25, 26
Large-signal transient response	27
Small-signal transient response	28
Overdrive recovery	29, 30
Voltage and current noise vs Frequency	31
Rejection ratios vs Frequency	32
Rejection ratios vs Case temperature	33
Output balance error vs Frequency	34
Open-loop gain and phase vs Frequency	35
Open-loop gain vs Case temperature	36
Input bias and offset current vs Case temperature	37
Quiescent current vs Supply voltage	38
Input offset voltage vs Case temperature	39
Common-mode rejection ratio vs Input common-mode range	40
Differential output current drive vs Case temperature	41
Harmonic distortion (single-ended and differential input to differential output) vs Output common-mode voltage	42
Small signal frequency response at V_{OCM}	43
Output offset voltage at V_{OCM} vs Output common-mode voltage	44
Quiescent current vs Power-down voltage	45
Turnon and turnoff delay times	46
Single-ended output impedance in power down vs Frequency	47
Power-down quiescent current vs Case temperature	48
Power-down quiescent current vs Supply voltage	49

TYPICAL CHARACTERISTICS
Table of Graphs (5 V)

	FIGURE
Small signal unity gain frequency response	50
Small signal frequency response	51
0.1 dB gain flatness frequency response	52
Harmonic distortion (single-ended input to differential output) vs Frequency	53, 54, 61, 63
Harmonic distortion (differential input to differential output) vs Frequency	55, 56, 62, 64
Harmonic distortion (single-ended input to differential output) vs Output voltage swing	57, 58, 65, 67
Harmonic distortion (differential input to differential output) vs Output voltage swing	59, 60, 66, 68
Harmonic distortion (single-ended input to differential output) vs Load resistance	69
Harmonic distortion (differential input to differential output) vs Load resistance	70
Slew rate vs Differential output voltage step	71
Large-signal transient response	72
Small-signal transient response	73
Voltage and current noise vs Frequency	74
Rejection ratios vs Frequency	75
Rejection ratios vs Case temperature	76
Output balance error vs Frequency	77
Open-loop gain and phase vs Frequency	78
Open-loop gain vs Case temperature	79
Input bias and offset current vs Case temperature	80
Quiescent current vs Supply voltage	81
Input offset voltage vs Case temperature	82
Common-mode rejection ratio vs Input common-mode range	83
Output drive vs Case temperature	84
Harmonic distortion (single-ended and differential input) vs Output common-mode range	85
Small signal frequency response at V_{OCM}	86
Output offset voltage vs Output common-mode voltage	87
Quiescent current vs Power-down voltage	88
Turnon and turnoff delay times	89
Single-ended output impedance in power down vs Frequency	90
Power-down quiescent current vs Case temperature	91
Power-down quiescent current vs Supply voltage	92

TYPICAL CHARACTERISTICS (± 5 V Graphs)

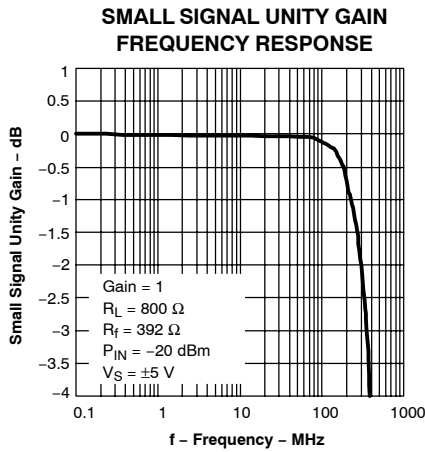


Figure 2

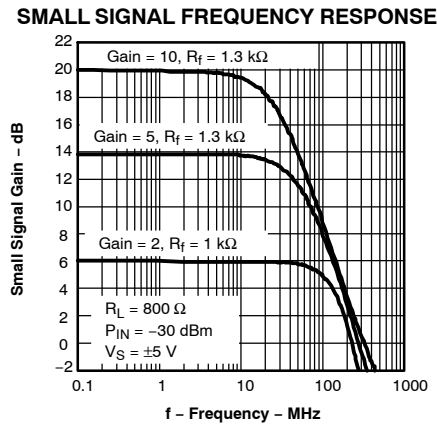


Figure 3

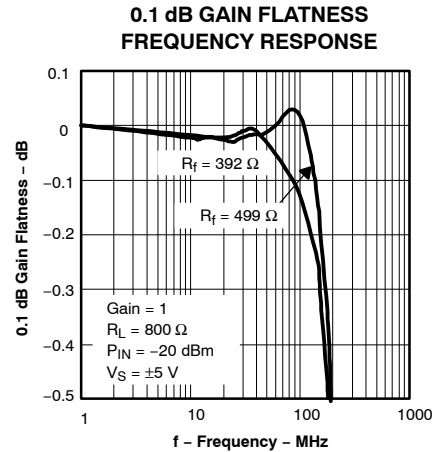


Figure 4

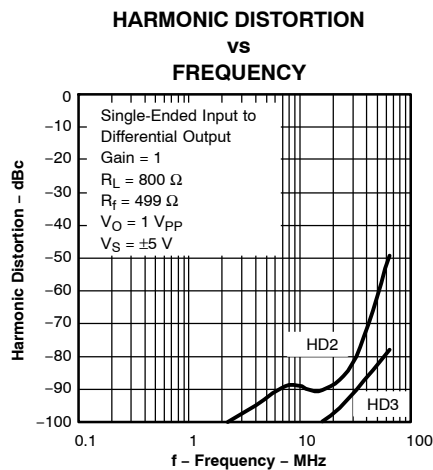


Figure 5

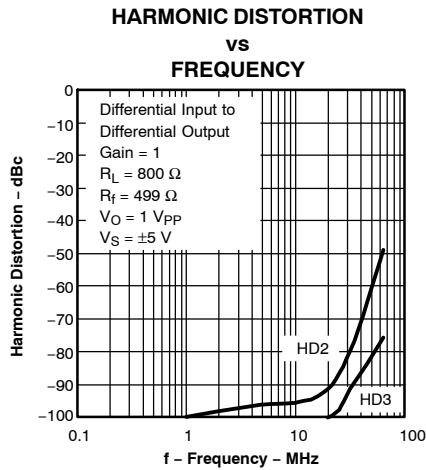


Figure 6

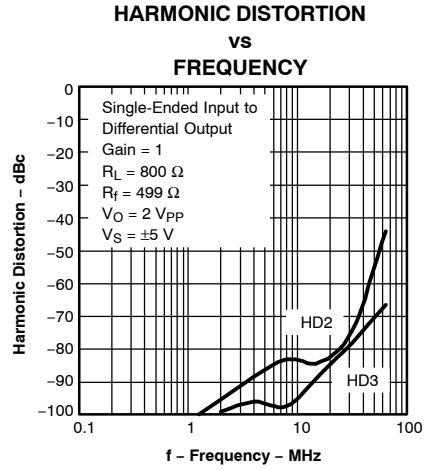


Figure 7

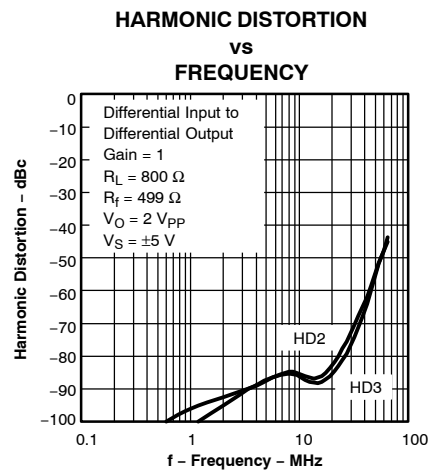


Figure 8

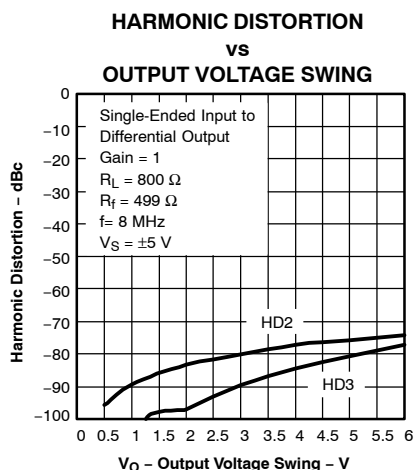


Figure 9

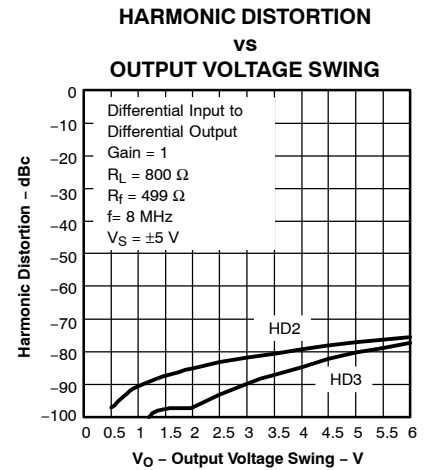


Figure 10

TYPICAL CHARACTERISTICS (± 5 V Graphs)

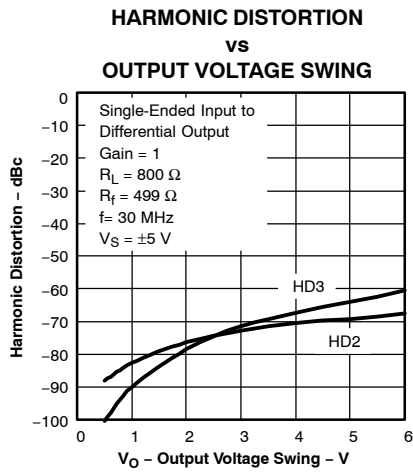


Figure 11

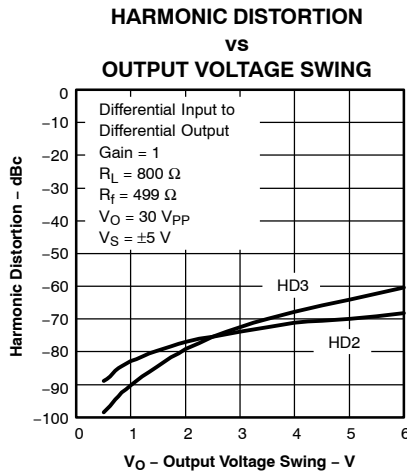


Figure 12

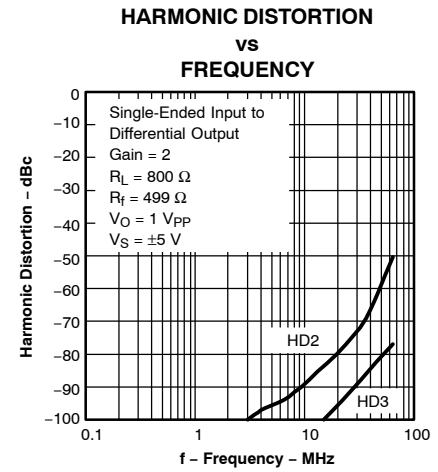


Figure 13

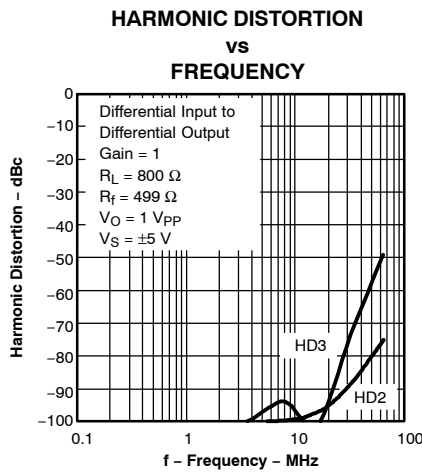


Figure 14

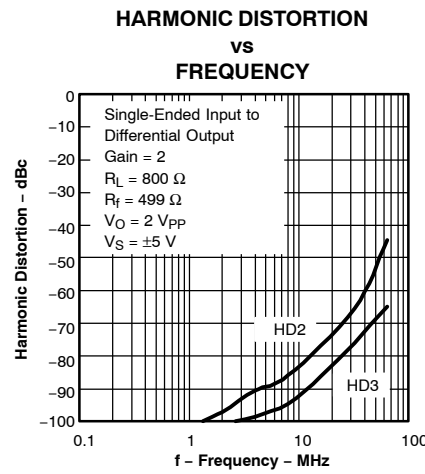


Figure 15

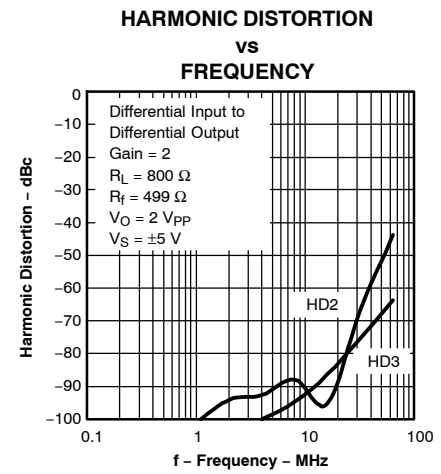


Figure 16

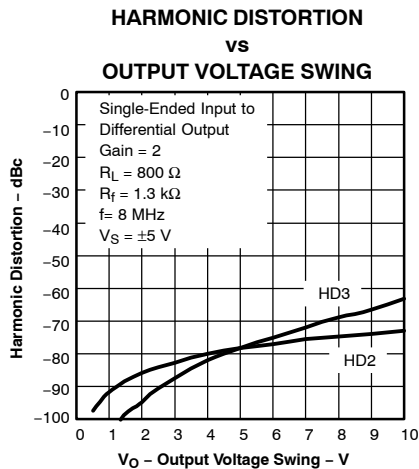


Figure 17

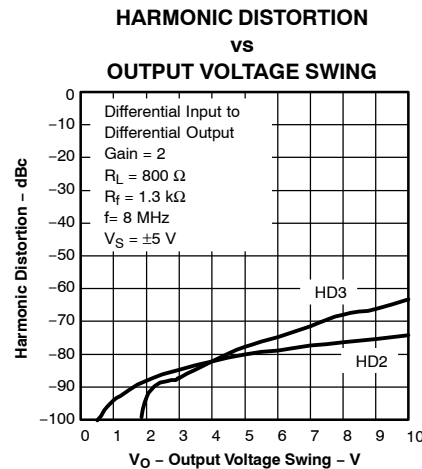


Figure 18

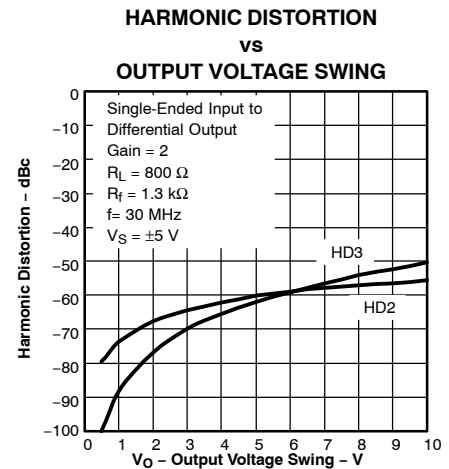


Figure 19

TYPICAL CHARACTERISTICS (± 5 V Graphs)

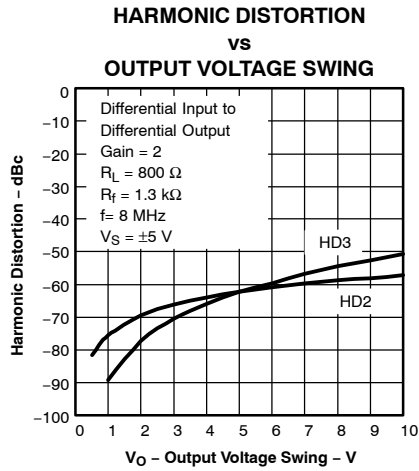


Figure 20

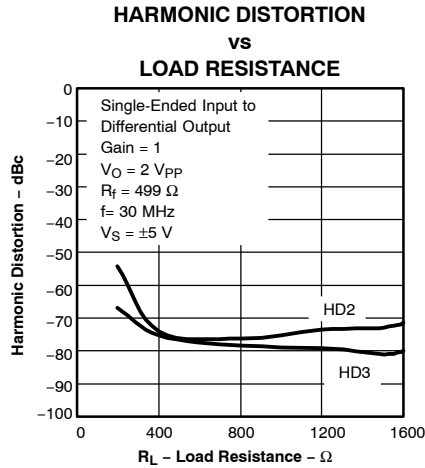


Figure 21

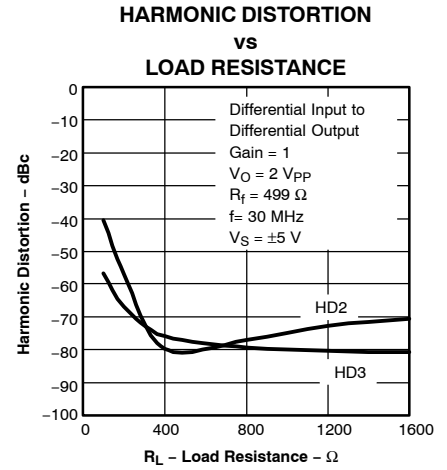


Figure 22

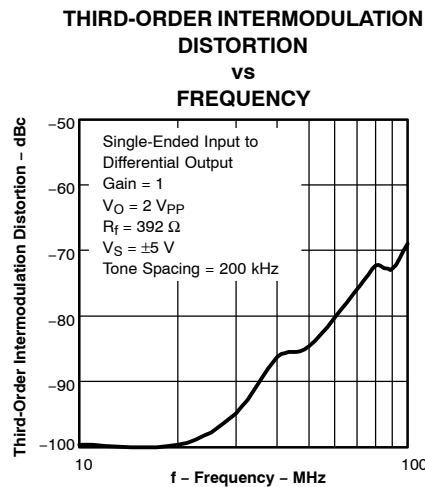


Figure 23

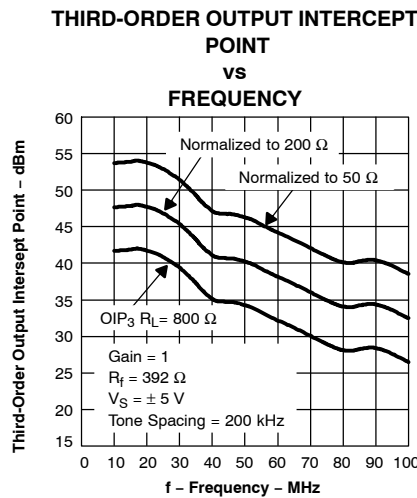


Figure 24

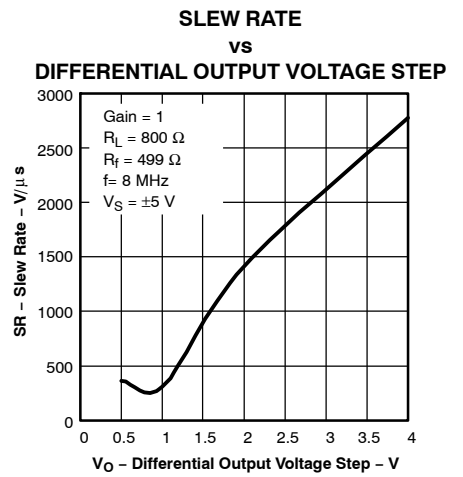


Figure 25

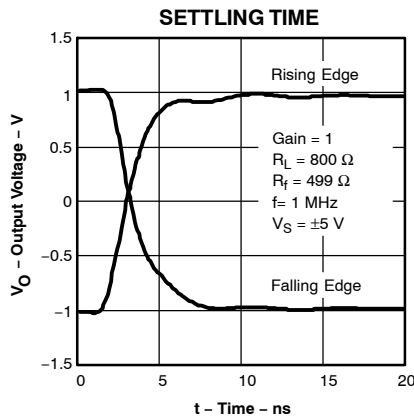


Figure 26

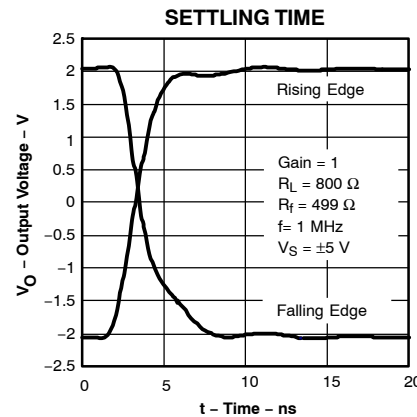


Figure 27

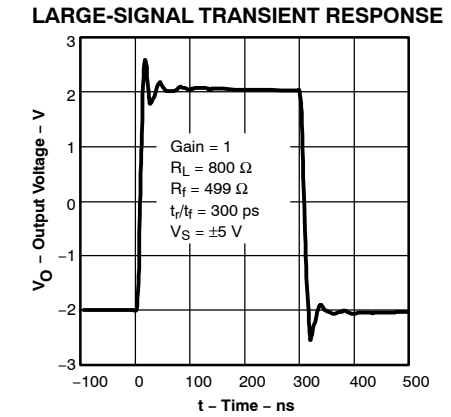


Figure 28

TYPICAL CHARACTERISTICS (± 5 V Graphs)

SMALL-SIGNAL TRANSIENT RESPONSE

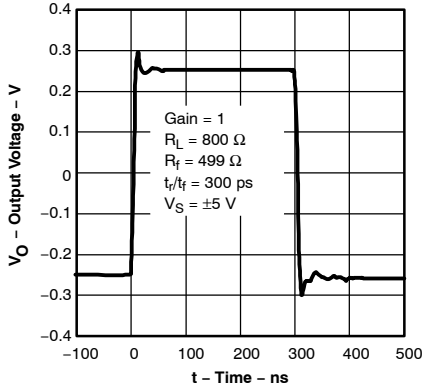


Figure 29

OVERDRIVE RECOVERY

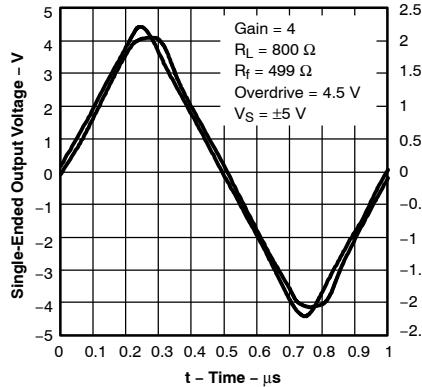


Figure 30

OVERDRIVE RECOVERY

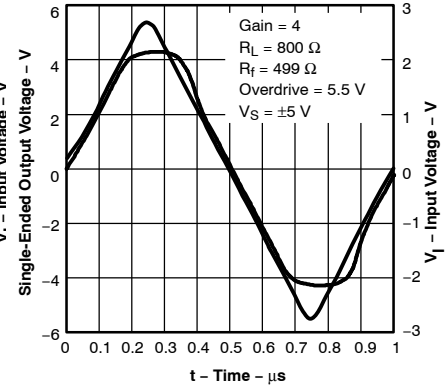


Figure 31

VOLTAGE AND CURRENT NOISE
VS
FREQUENCY

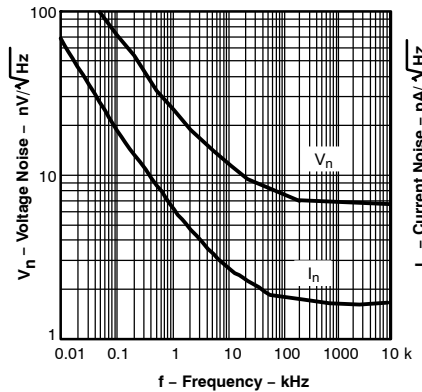


Figure 32

REJECTION RATIOS
VS
FREQUENCY

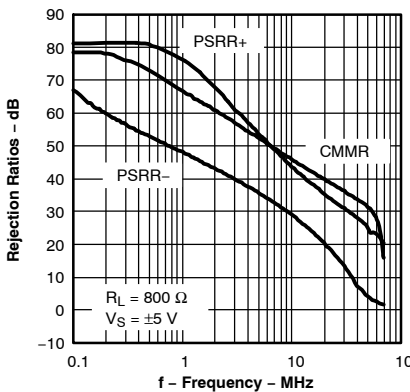


Figure 33

REJECTION RATIOS
VS
CASE TEMPERATURE

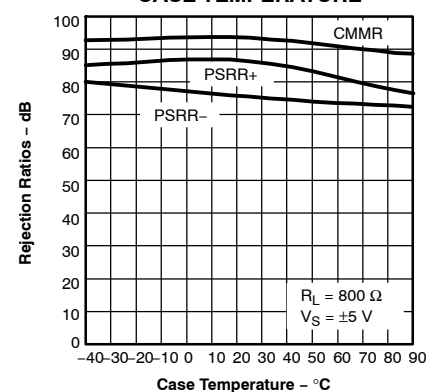


Figure 34

OUTPUT BALANCE ERROR
VS
FREQUENCY

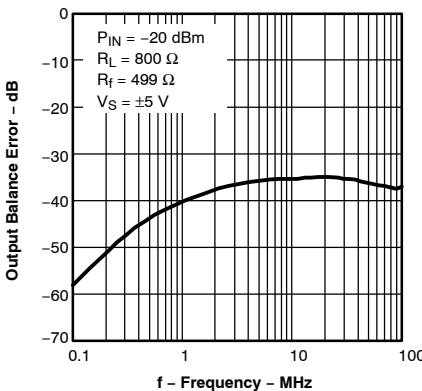


Figure 35

OPEN-LOOP GAIN AND PHASE
VS
FREQUENCY

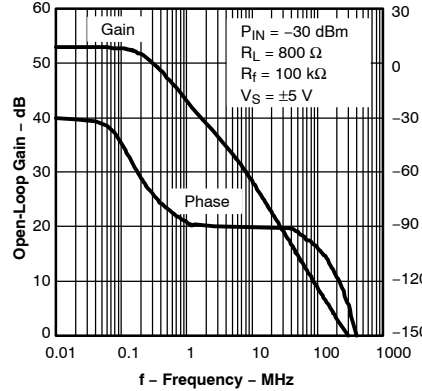


Figure 36

OPEN-LOOP GAIN
VS
CASE TEMPERATURE

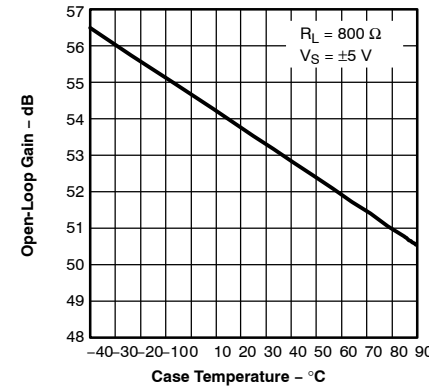


Figure 37

TYPICAL CHARACTERISTICS (± 5 V Graphs)

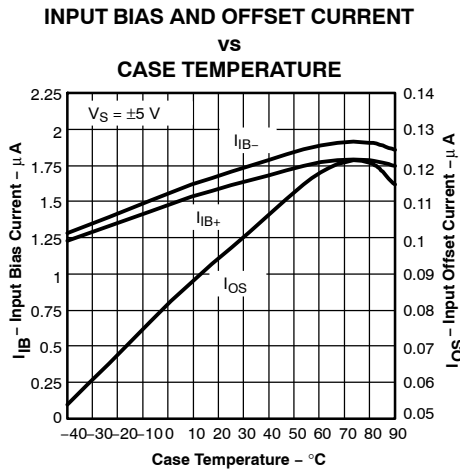


Figure 38

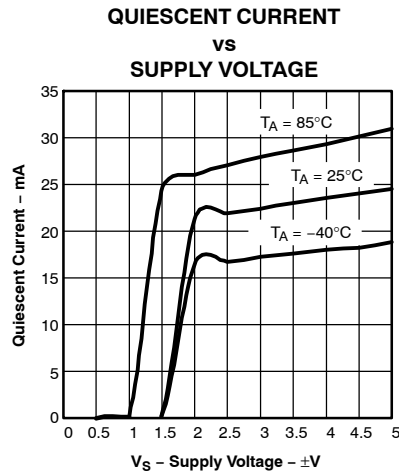


Figure 39

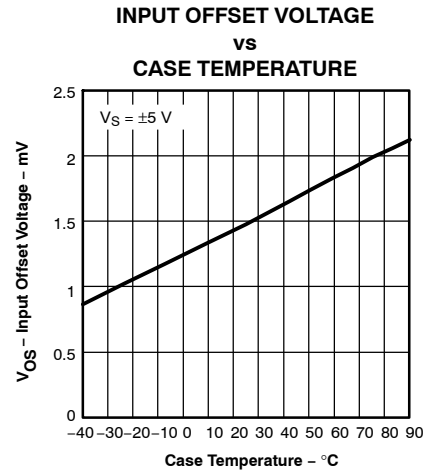


Figure 40

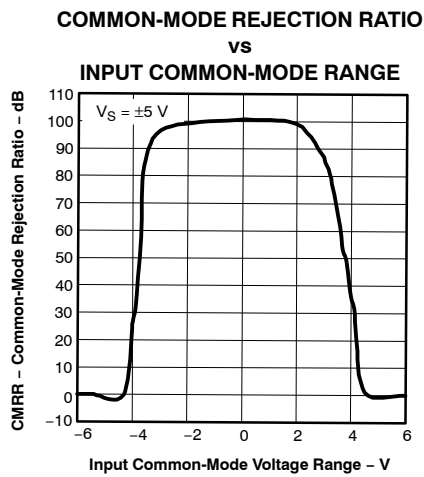


Figure 41

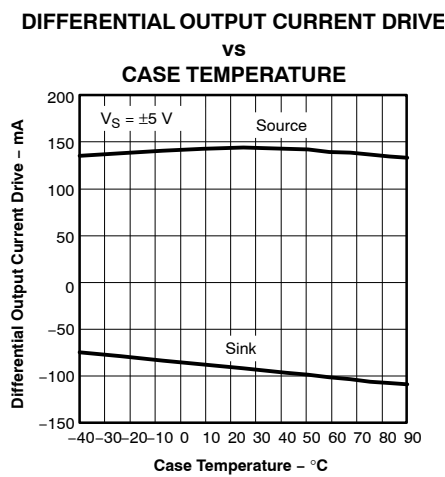


Figure 42

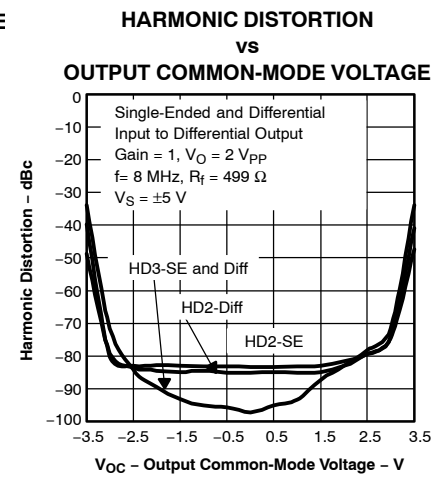


Figure 43

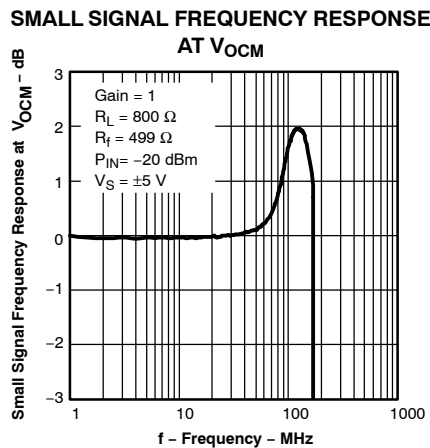


Figure 44

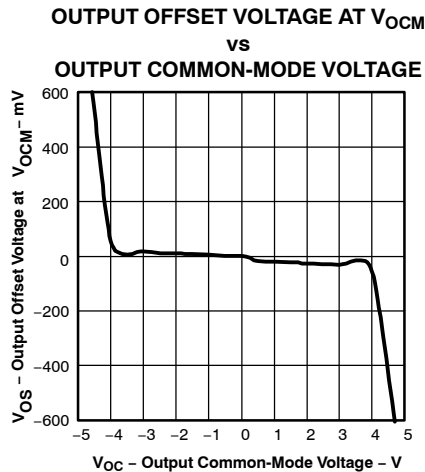


Figure 45

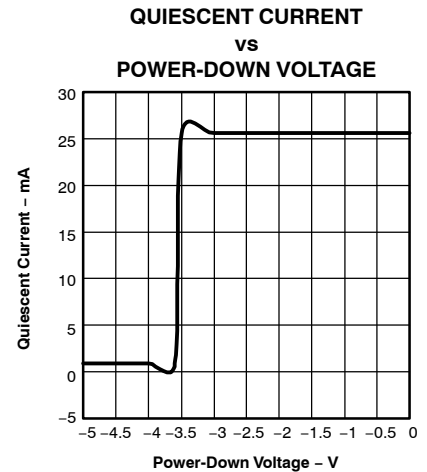


Figure 46

TYPICAL CHARACTERISTICS (± 5 V Graphs)

TURNON AND TURNOFF DELAY TIMES

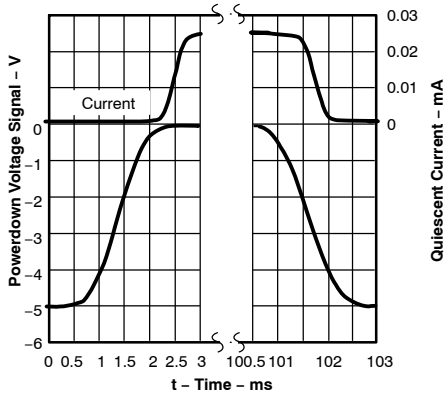


Figure 47

SINGLE-ENDED OUTPUT IMPEDANCE
IN POWER DOWN
vs
FREQUENCY

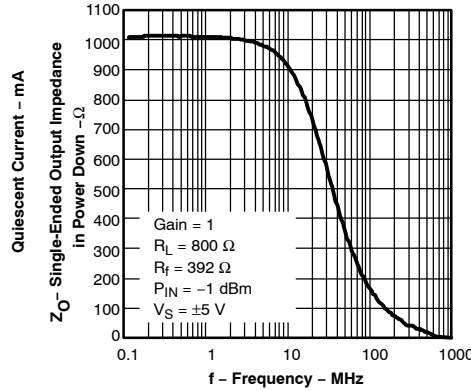


Figure 48

POWER-DOWN QUIESCENT CURRENT
vs
CASE TEMPERATURE

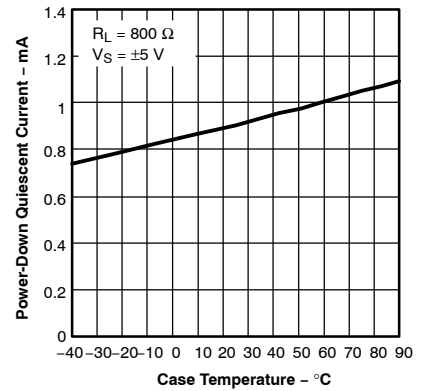


Figure 49

POWER-DOWN QUIESCENT CURRENT
vs
SUPPLY VOLTAGE

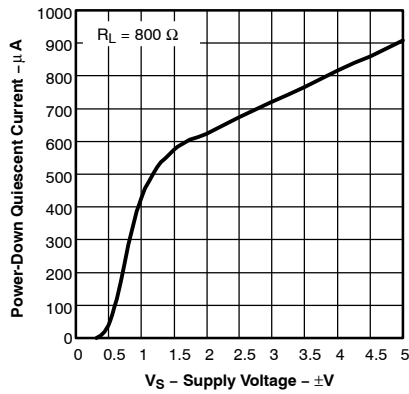


Figure 50

TYPICAL CHARACTERISTICS (5 V Graphs)

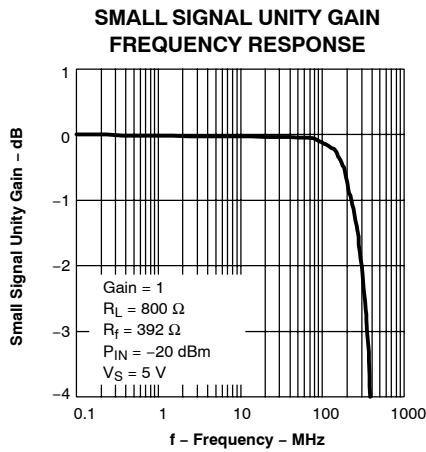


Figure 51

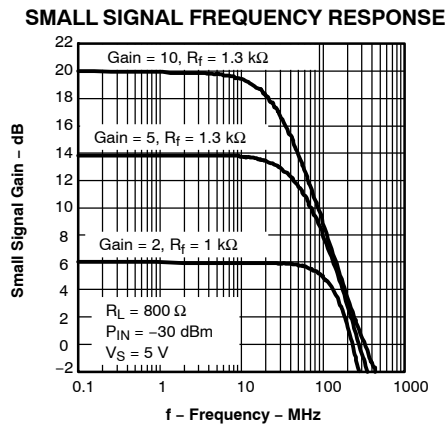


Figure 52

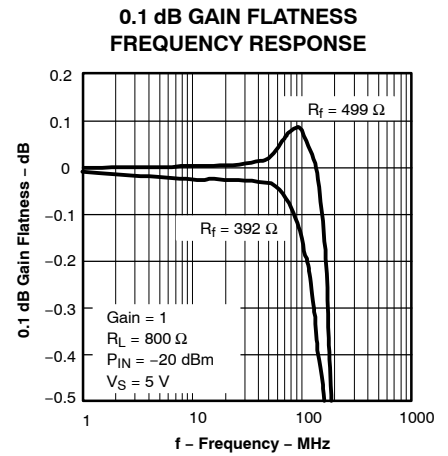


Figure 53

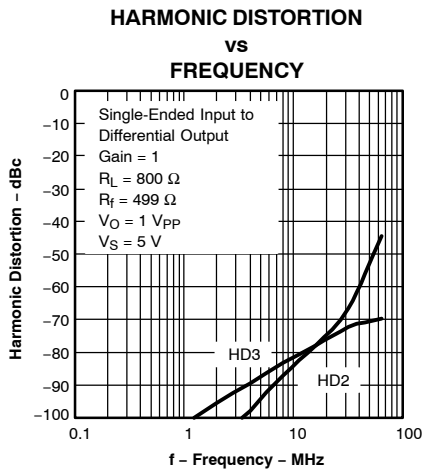


Figure 54

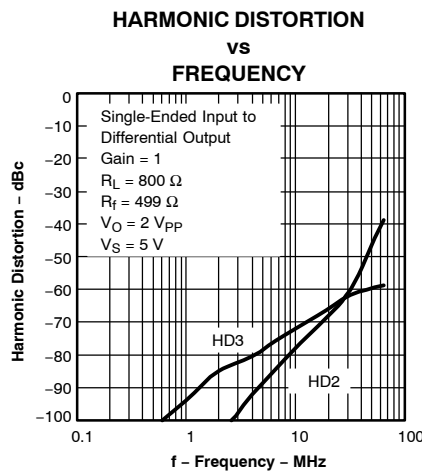


Figure 55

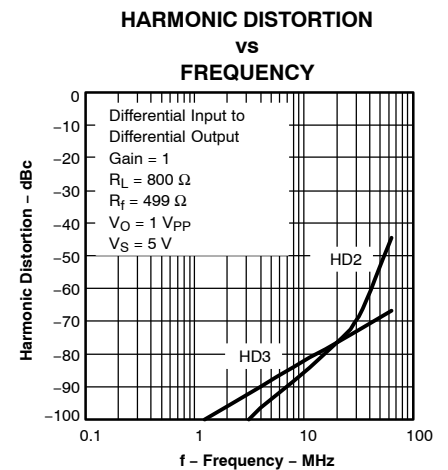


Figure 56

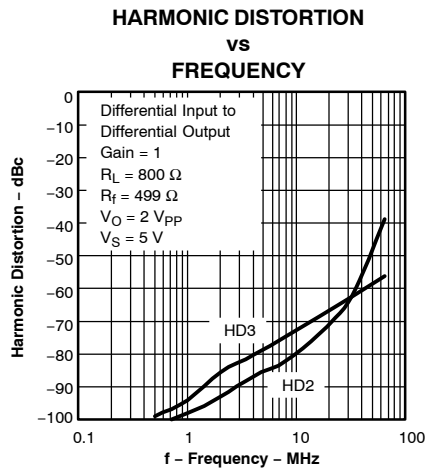


Figure 57

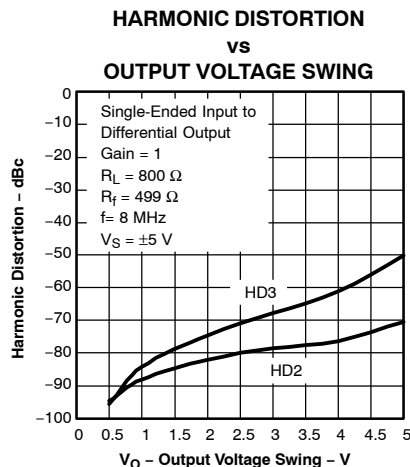


Figure 58

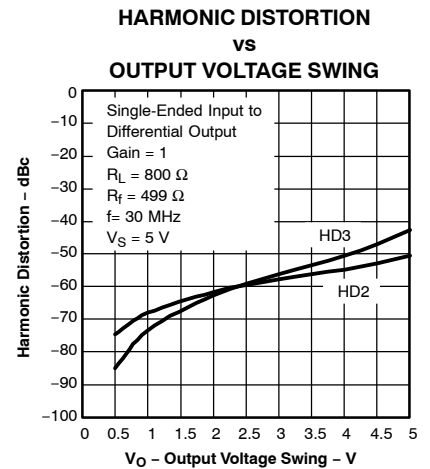


Figure 59

TYPICAL CHARACTERISTICS (5 V Graphs)

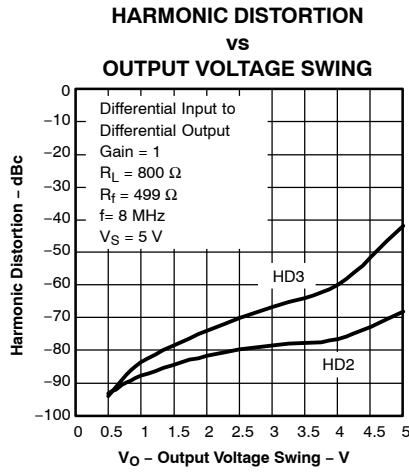


Figure 60

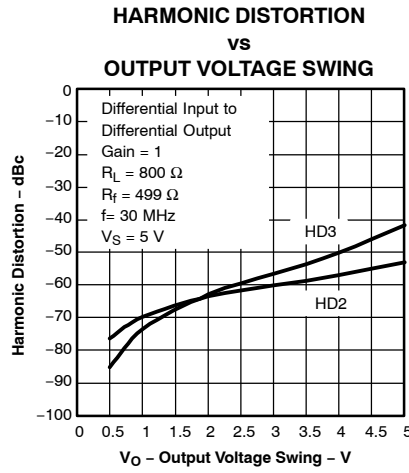


Figure 61

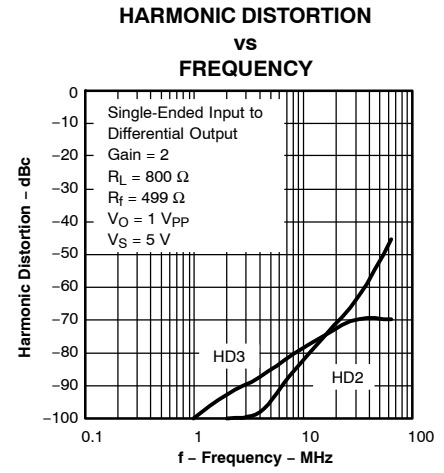


Figure 62

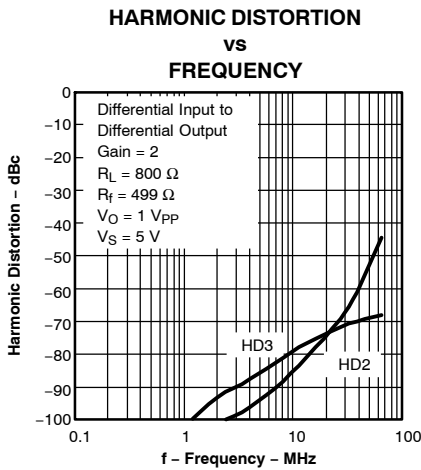


Figure 63

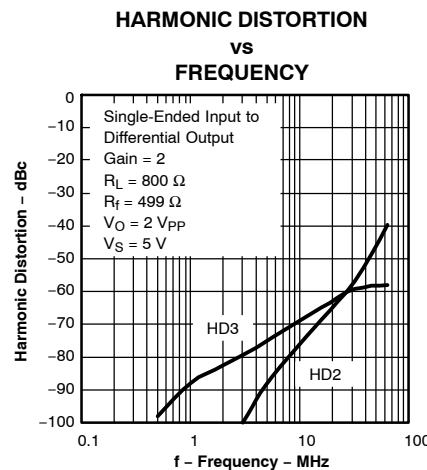


Figure 64

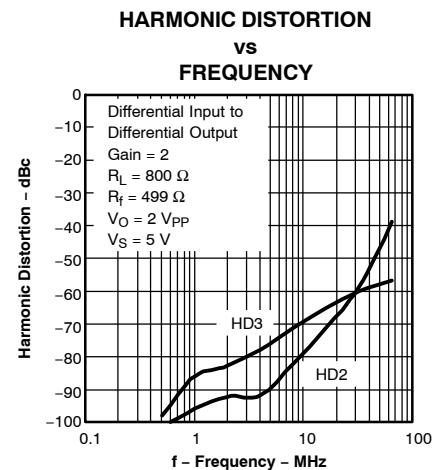


Figure 65

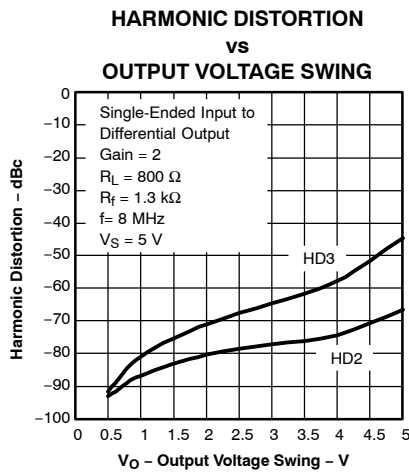


Figure 66

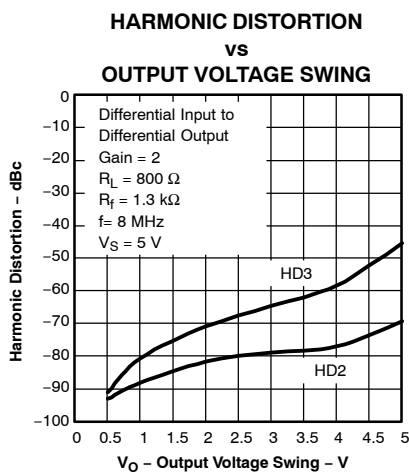


Figure 67

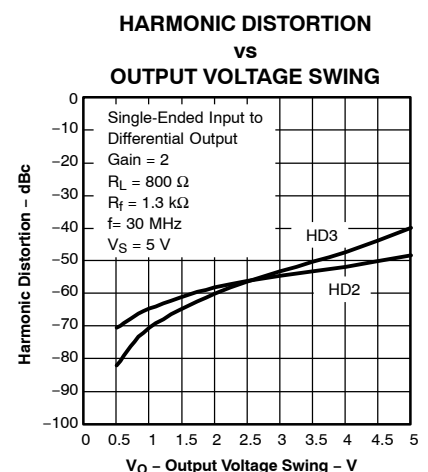


Figure 68

TYPICAL CHARACTERISTICS (5 V Graphs)

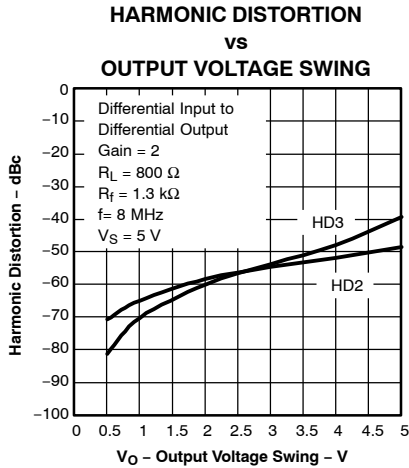


Figure 69

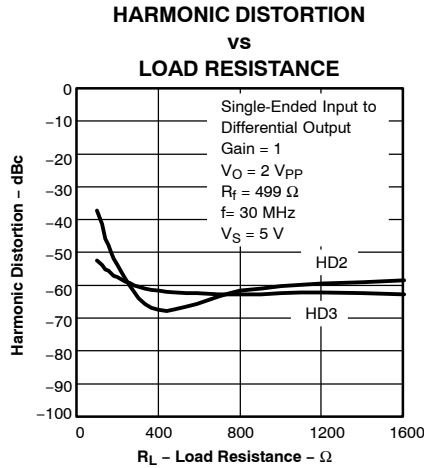


Figure 70

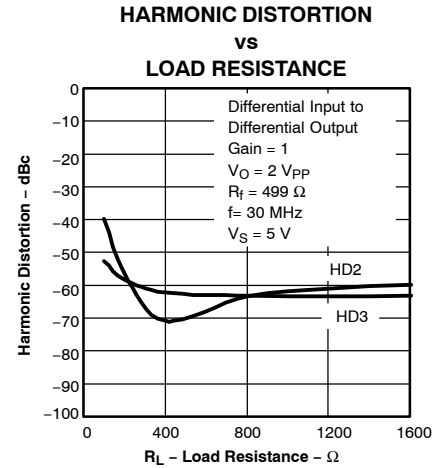


Figure 71

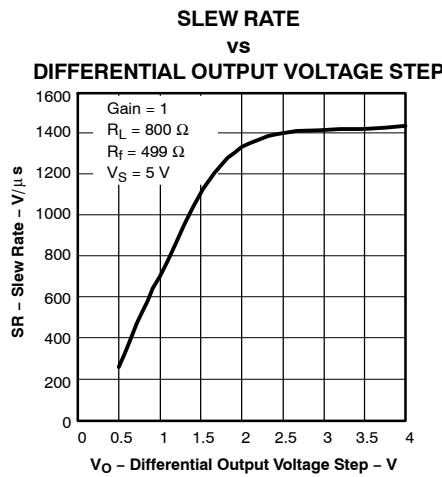


Figure 72

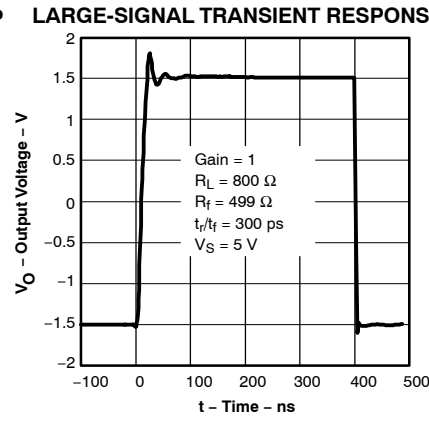


Figure 73

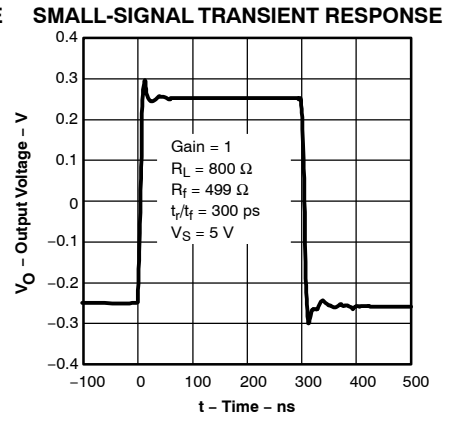


Figure 74

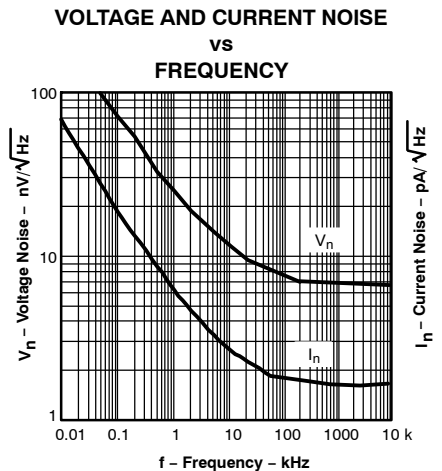


Figure 75

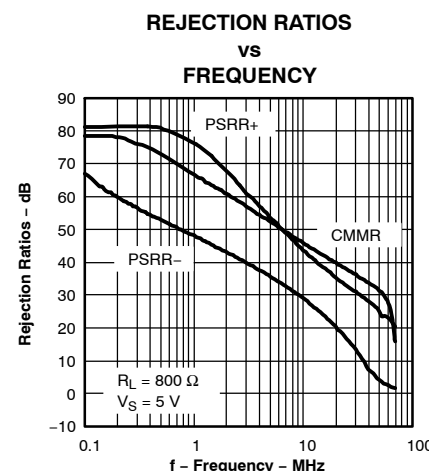


Figure 76

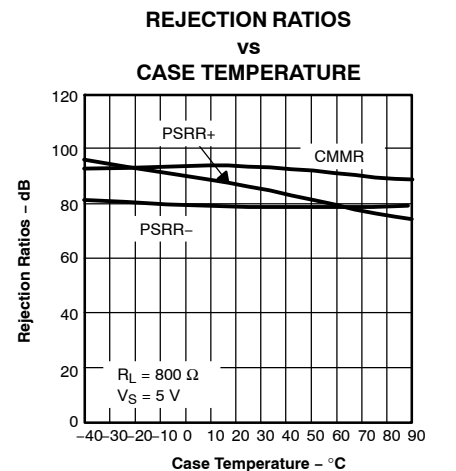


Figure 77

TYPICAL CHARACTERISTICS (5 V Graphs)

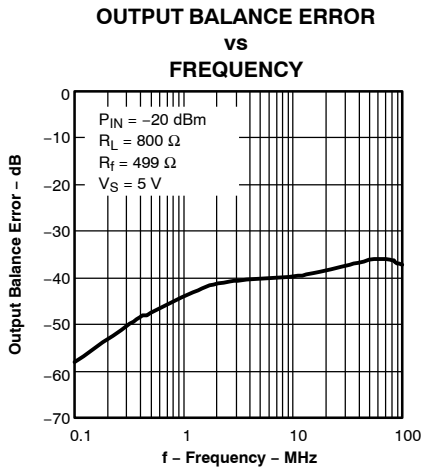


Figure 78

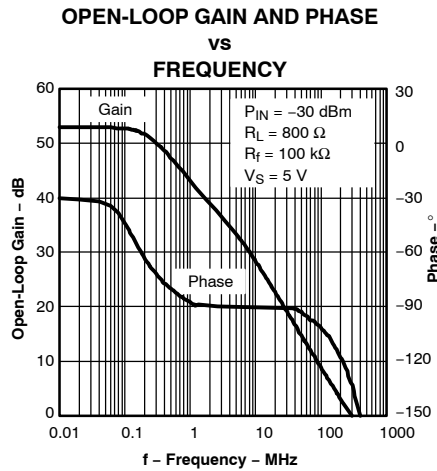


Figure 79

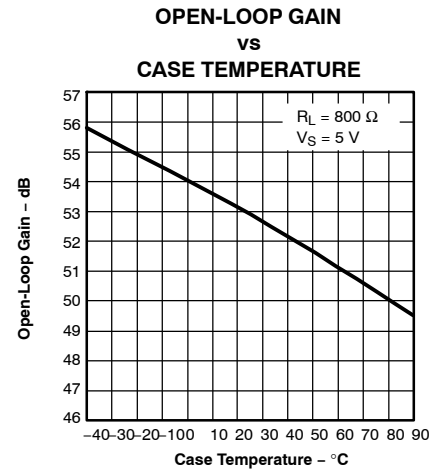


Figure 80

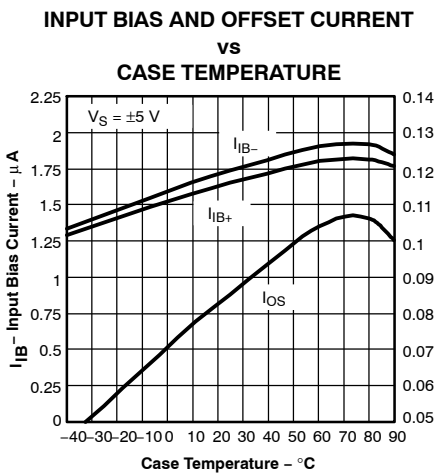


Figure 81

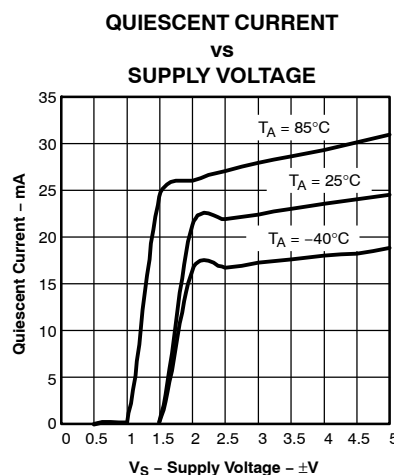


Figure 82

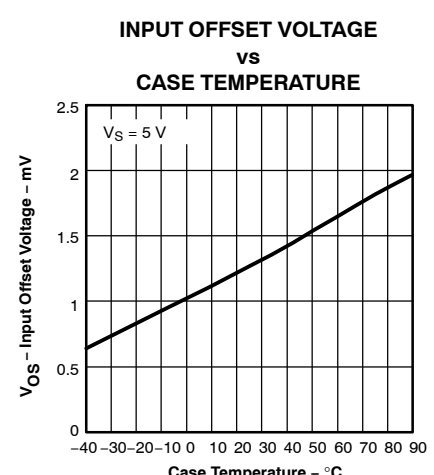


Figure 83

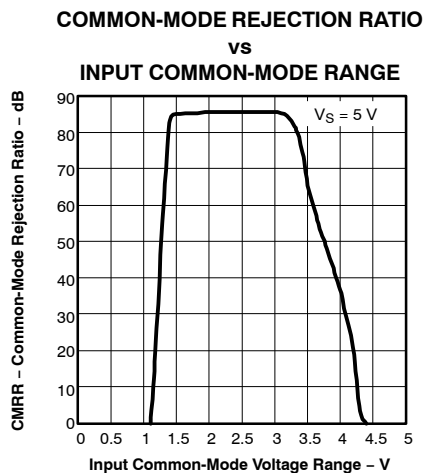


Figure 84

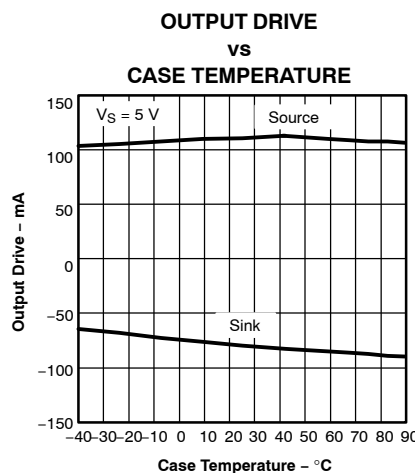


Figure 85

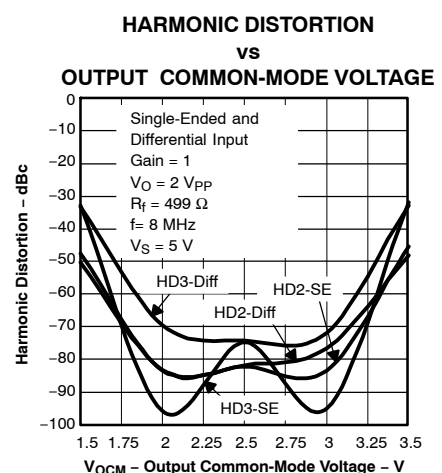


Figure 86

TYPICAL CHARACTERISTICS

SMALL SIGNAL FREQUENCY RESPONSE
at V_{OCM}

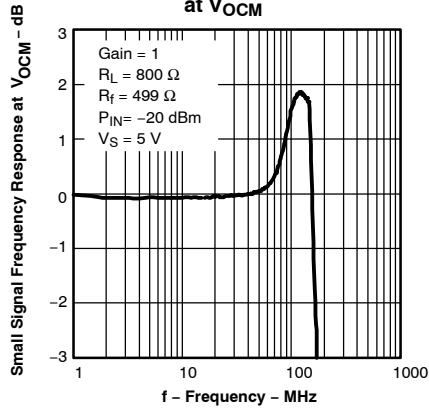


Figure 87

OUTPUT OFFSET VOLTAGE
vs
OUTPUT COMMON-MODE VOLTAGE

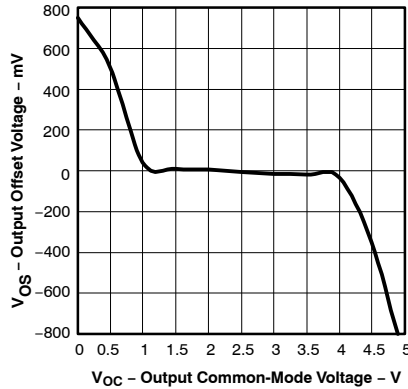


Figure 88

QUIESCENT CURRENT
vs
POWER-DOWN VOLTAGE

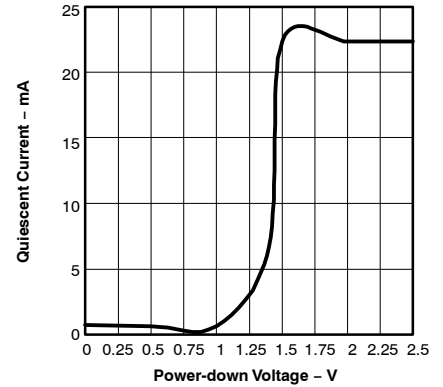


Figure 89

TURNON AND TUNOFF DELAY TIMES

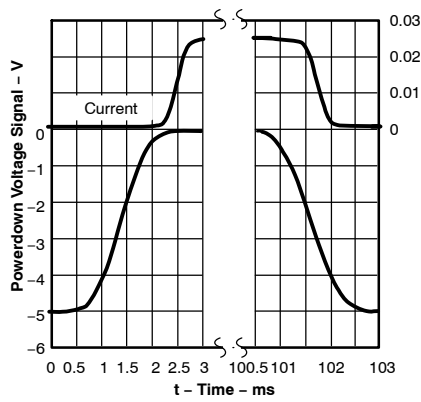


Figure 90

SINGLE-ENDED OUTPUT IMPEDANCE
IN POWER DOWN vs FREQUENCY

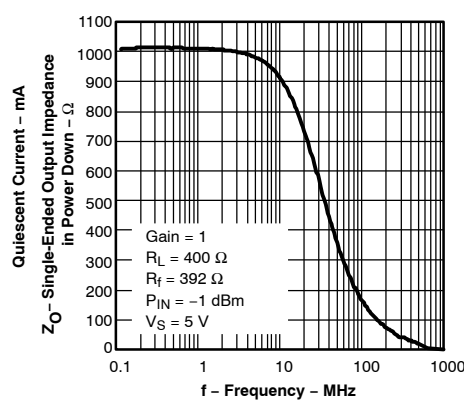


Figure 91

POWER-DOWN QUIESCENT CURRENT
vs
CASE TEMPERATURE

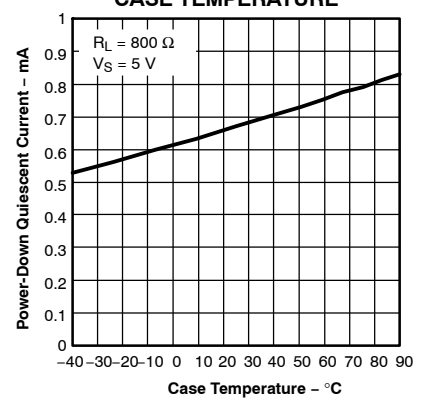


Figure 92

POWER-DOWN QUIESCENT CURRENT
vs
SUPPLY VOLTAGE

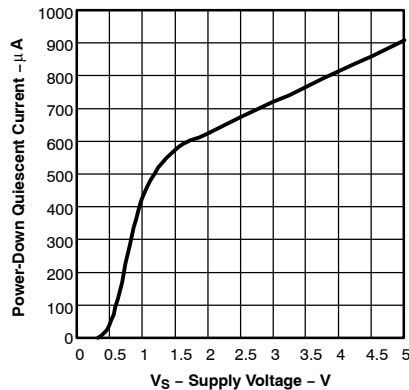


Figure 93

APPLICATION INFORMATION

MAXIMUM DIE TEMPERATURE TO PREVENT OSCILLATION

The THS4503 may have low level oscillation when the die temperature (also called junction temperature) exceeds +60°C and is not recommended for new designs where the die temperature is expected to exceed +60°C.

The oscillation is due to internal design and external configuration is not expected to mitigate or reduce the problem. This problem is random due to normal process variations and normal testing cannot identify problem units.

The THS4500 and THS4501 are recommended replacement devices.

The die temperature depends on the power dissipation and the thermal resistance of the device and can be approximated with the following formula:

$$\text{Die Temperature} = P_{\text{DISS}} \times \theta_{\text{JA}} + T_{\text{A}}$$

Where:

$$P_{\text{DISS}} \approx (V_{\text{S(TOTAL)}} \times I_{\text{Q}}) + (V_{\text{S+}} - V_{\text{OUT}}) \times I_{\text{OUT}} \times \theta_{\text{JA}} + T_{\text{A}}$$

Table 1 shows the estimated maximum ambient temperature ($T_{\text{A max}}$) in °C for package option of the THS4503 using the thermal dissipation rating given in the PACKAGE DISSIPATION RATINGS table for a JEDEC standard High-K test PCB. For each case shown, $V_{\text{S(TOTAL)}} = 10\text{V}$, $R_{\text{L}} = 800\ \Omega$ differential, and the quiescent current = 32mA (the maximum over 0°C to 70°C temperature range). The last entry for each package option lists the worst case where the output voltage is 5V DC.

Table 1. Estimated Maximum Ambient Temperature Per Package Option

Package/Device PWR Pad MSOP	Vout	θ_{JA}	$T_{\text{A max}}$
THS4503DGN	0 V	58.4°C/W	41.3°C
	2 Vpp		40.8°C
	4 Vpp		40.4°C
	6 Vpp		40.1°C
	8 Vpp		39.8°C
Worst Case	5 DC		39.5°C

FULLY DIFFERENTIAL AMPLIFIERS

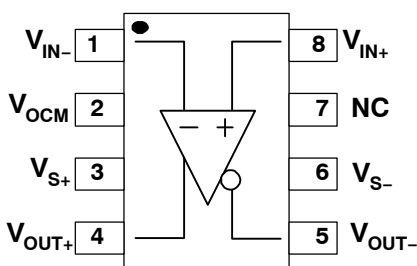
Differential signaling offers a number of performance advantages in high-speed analog signal processing systems, including immunity to external common-mode noise, suppression of even-order nonlinearities, and increased dynamic range. Fully differential amplifiers not only serve as the primary means of providing gain to a differential signal chain, but also provide a monolithic solution for converting single-ended signals into differential signals for easier, higher performance processing. The THS4500 family of amplifiers contains products in Texas Instruments' expanding line of high-performance fully differential amplifiers. Information on fully differential amplifier fundamentals, as well as implementation specific information, is presented in the applications section of this data sheet to provide a better understanding of the operation of the THS4500 family of devices and to simplify the design process for designs using these amplifiers.

Applications Section

- Fully Differential Amplifier Terminal Functions
- Input Common-Mode Voltage Range and the THS4500 Family
- Choosing the Proper Value for the Feedback and Gain Resistors
- Application Circuits Using Fully Differential Amplifiers
- Key Design Considerations for Interfacing to an Analog-to-Digital Converter
- Setting the Output Common-Mode Voltage With the V_{OCM} Input
- Saving Power With Power-Down Functionality
- Linearity: Definitions, Terminology, Circuit Techniques, and Design Tradeoffs
- An Abbreviated Analysis of Noise in Fully Differential Amplifiers
- Printed-Circuit Board Layout Techniques for Optimal Performance
- Power Dissipation and Thermal Considerations
- Power Supply Decoupling Techniques and Recommendations
- Evaluation Fixtures, Spice Models, and Applications Support
- Additional Reference Material

FULLY DIFFERENTIAL AMPLIFIER TERMINAL FUNCTIONS

Fully differential amplifiers are typically packaged in 8-pin packages as shown in the diagram. The device pins include two inputs (V_{IN+} , V_{IN-}), two outputs (V_{OUT-} , V_{OUT+}), two power supplies (V_{S+} , V_{S-}), an output common-mode control pin (V_{OCM}), and an optional power-down pin (PD).

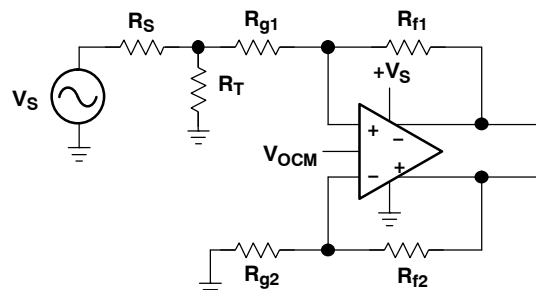


Fully Differential Amplifier Pin Diagram

A standard configuration for the device is shown in the figure. The functionality of a fully differential amplifier can be imagined as two inverting amplifiers that share a common noninverting terminal (though the voltage is not necessarily fixed). For more information on the basic theory of operation for fully differential amplifiers, see the Texas Instruments application note titled *Fully Differential Amplifiers* (SLOA054).

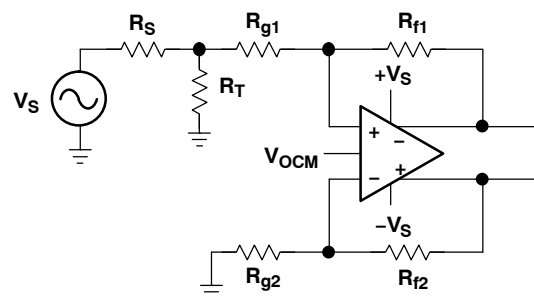
INPUT COMMON-MODE VOLTAGE RANGE AND THE THS4500 FAMILY

The key difference between the THS4500/1 and the THS4502/3 is the input common-mode range for the two devices. The THS4503 has an input common-mode range that is centered around midrail, and the THS4500 and THS4501 have an input common-mode range that is shifted to include the negative power supply rail. Selection of one or the other is determined by the nature of the application. Specifically, the THS4500 and THS4501 are designed for use in single-supply applications where the input signal is ground-referenced, as depicted in Figure 94. The THS4503 is designed for use in single-supply or split-supply applications where the input signal is centered between the power supply voltages, as depicted in Figure 95.



Application Circuit for the THS4500 and THS4501, Featuring Single-Supply Operation With a Ground-Referenced Input Signal

Figure 94



Application Circuit for the THS4500 and THS4501, Featuring Split-Supply Operation With an Input Signal Referenced at the Midrail

Figure 95

Equations 1–5 allow for calculation of the required input common-mode range for a given set of input conditions.

The equations allow calculation of the input common-mode range requirements given information about the input signal, the output voltage swing, the gain, and the output common-mode voltage. Calculating the maximum and minimum voltage required for V_N and V_P (the amplifier's input nodes) determines whether or not the input common-mode range is violated or not. Four equations are required. Two calculate the output voltages and two calculate the node voltages at V_N and V_P (note that only one of these needs calculation, as the amplifier forces a virtual short between the two nodes).

THS4503-EP

SGLS291A – APRIL 2005 – JANUARY 2012

$$V_{OUT+} = \frac{V_{IN+}(1-\beta) - V_{IN-}(1-\beta) + 2V_{OCM}\beta}{2\beta} \quad (1)$$

$$V_{OUT-} = \frac{-V_{IN+}(1-\beta) + V_{IN-}(1-\beta) + 2V_{OCM}\beta}{2\beta} \quad (2)$$

$$V_N = V_{IN-}(1-\beta) + V_{OUT+}\beta \quad (3)$$

$$\text{Where: } \beta = \frac{R_G}{R_F + R_G} \quad (4)$$

$$V_P = V_{IN+}(1-\beta) + V_{OUT-}\beta \quad (5)$$

NOTE:

The equations denote the device inputs as V_N and V_P and the circuit inputs as V_{IN+} and V_{IN-} .

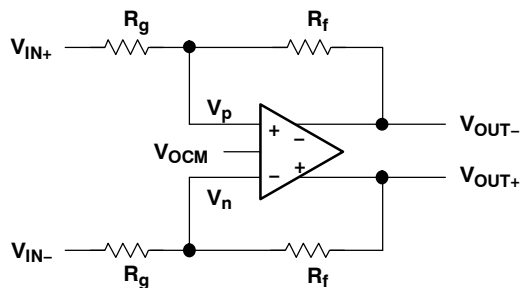


Diagram For Input Common-Mode Range Equations

Figure 96

The two tables below depict the input common-mode range requirements for two different input scenarios, an input referenced around the negative rail and an input referenced around midrail. The tables highlight the differing requirements on input common-mode range, and illustrate reasoning for choosing either the THS4500/1 or the THS4503. For signals referenced around the negative power supply, the THS4500/1 should be chosen since its input common-mode range includes the negative supply rail. For all other situations, the THS4503 offers slightly improved distortion and noise performance for applications with input signals centered between the power supply rails.

Table 2. Negative-Rail Referenced

Gain (V/V)	V_{IN+} (V)	V_{IN-} (V)	V_{IN} (V _{PP})	V_{OCM} (V)	V_{OD} (V _{PP})	V_{NMIN} (V)	V_{NMAX} (V)
1	-2 to 2	0	4	2.5	4	0.75	1.75
2	-1 to 1	0	2	2.5	4	0.5	1.167
4	-0.5 to 0.5	0	1	2.5	4	0.3	0.7
8	-0.25 to 0.25	0	0.5	2.5	4	0.167	0.389

NOTE: This table assumes a negative-rail referenced, single-ended input signal on a single 5-V supply as shown in Figure 94.
 $V_{NMIN} = V_{PMIN}$ and $V_{NMAX} = V_{PMAX}$.

Table 3. Midrail Referenced

Gain (V/V)	V_{IN+} (V)	V_{IN-} (V)	V_{IN} (V _{PP})	V_{OCM} (V)	V_{OD} (V _{PP})	V_{NMIN} (V)	V_{NMAX} (V)
1	0.5 to 4.5	2.5	4	2.5	4	2	3
2	1.5 to 3.5	2.5	2	2.5	4	2.16	2.83
4	2 to 3	2.5	1	2.5	4	2.3	2.7
8	2.25 to 2.75	2.5	0.5	2.5	4	2.389	2.61

NOTE: This table assumes a midrail referenced, single-ended input signal on a single 5-V supply.

$$V_{NMIN} = V_{PMIN} \text{ and } V_{NMAX} = V_{PMAX}$$

CHOOSING THE PROPER VALUE FOR THE FEEDBACK AND GAIN RESISTORS

The selection of feedback and gain resistors impacts circuit performance in a number of ways. The values in this section provide the optimum high frequency performance (lowest distortion, flat frequency response). Since the THS4500 family of amplifiers is developed with a voltage feedback architecture, the choice of resistor values does not have a dominant effect on bandwidth, unlike a current feedback amplifier. However, resistor choices do have second-order effects. For optimal performance, the following feedback resistor values are recommended. In higher gain configurations (gain greater than two), the feedback resistor values have much less effect on the high frequency performance. Example feedback and gain resistor values are given in the section on basic design considerations (see Table 4).

Amplifier loading, noise, and the flatness of the frequency response are three design parameters that should be considered when selecting feedback resistors. Larger resistor values contribute more noise and can induce peaking in the ac response in low gain configurations, and smaller resistor values can load the amplifier more heavily, resulting in a reduction in distortion performance. In addition, feedback resistor values, coupled with gain requirements, determine the value of the gain resistors, directly impacting the input impedance of the entire circuit. While there are no strict rules about resistor selection, these trends can provide qualitative design guidance.

APPLICATION CIRCUITS USING FULLY DIFFERENTIAL AMPLIFIERS

Fully differential amplifiers provide designers with a great deal of flexibility in a wide variety of applications. This section provides an overview of some common circuit configurations and gives some design guidelines. Designing the interface to an ADC, driving lines differentially, and filtering with fully differential amplifiers are a few of the circuits that are covered.

BASIC DESIGN CONSIDERATIONS

The circuits in Figure 96 through Figure 100 are used to highlight basic design considerations for fully differential amplifier circuit designs.

Table 4. Resistor Values for Balanced Operation in Various Gain Configurations

Gain $\left(\frac{V_{OD}}{V_{IN}}\right)$	R2 and R4 (Ω)	R1 (Ω)	R3 (Ω)	R _T (Ω)
1	392	412	383	54.9
1	499	523	487	53.6
2	392	215	187	60.4
2	1.3 k	665	634	52.3
5	1.3 k	274	249	56.2
5	3.32 k	681	649	52.3
10	1.3 k	147	118	64.9
10	6.81 k	698	681	52.3

NOTE: Values in the table above assume a 50- Ω source impedance.

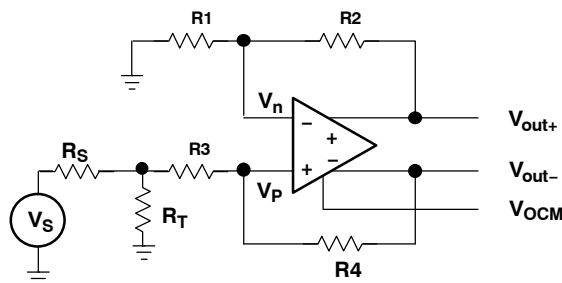


Figure 97

Equations for calculating fully differential amplifier resistor values in order to obtain balanced operation in the presence of a 50- Ω source impedance are given in equations 6 through 9.

$$R_T = \frac{1}{\frac{1}{R_S} - \frac{K}{2(1+K)R_3}} \quad K = \frac{R_2}{R_1} \quad R_2 = R_4 \quad (6)$$

$$R_3 = R_1 - (R_S \parallel R_T)$$

$$\beta_1 = \frac{R_1}{R_1 + R_2} \quad \beta_2 = \frac{R_3 + R_T \parallel R_S}{R_3 + R_T \parallel R_S + R_4} \quad (7)$$

$$\frac{V_{OD}}{V_S} = 2 \left(\frac{1 - \beta_2}{\beta_1 + \beta_2} \right) \left(\frac{R_T}{R_T + R_S} \right) \quad (8)$$

$$\frac{V_{OD}}{V_{IN}} = 2 \left(\frac{1 - \beta_2}{\beta_1 + \beta_2} \right) \quad (9)$$

For more detailed information about balance in fully differential amplifiers, see *Fully Differential Amplifiers*, referenced at the end of this data sheet.

INTERFACING TO AN ANALOG-TO-DIGITAL CONVERTER

The THS4500 family of amplifiers are designed specifically to interface to today's highest-performance analog-to-digital converters. This section highlights the key concerns when interfacing to an ADC and provides example ADC/fully differential amplifier interface circuits.

Key design concerns when interfacing to an analog-to-digital converter:

- Terminate the input source properly. In high-frequency receiver chains, the source feeding the fully differential amplifier requires a specific load impedance (e.g., 50 Ω).
- Design a symmetric printed-circuit board layout. Even-order distortion products are heavily influenced by layout, and careful attention to a symmetric layout will minimize these distortion products.
- Minimize inductance in power supply decoupling traces and components. Poor power supply decoupling can have a dramatic effect on circuit performance. Since the outputs are differential, differential currents exist in the power supply pins. Thus, decoupling capacitors should be placed in a manner that minimizes the impedance of the current loop.
- Use separate analog and digital power supplies and grounds. Noise (bounce) in the power supplies (created by digital switching currents) can couple directly into the signal path, and power supply noise can create higher distortion products as well.
- Use care when filtering. While an RC low-pass filter may be desirable on the output of the amplifier to filter broadband noise, the excess loading can negatively impact the amplifier linearity. Filtering in the feedback path does not have this effect.
- AC-coupling allows easier circuit design. If dc-coupling is required, be aware of the excess power dissipation that can occur due to level-shifting the output through the output common-mode voltage control.
- Do not terminate the output unless required. Many open-loop, class-A amplifiers require 50- Ω termination for proper operation, but closed-loop fully differential amplifiers drive a specific output voltage regardless of the load impedance present. Terminating the output of a fully differential amplifier with a heavy load adversely effects the amplifier's linearity.
- Comprehend the V_{OCM} input drive requirements. Determine if the ADC's voltage reference can provide the required amount of current to move V_{OCM} to the desired value. A buffer may be needed.

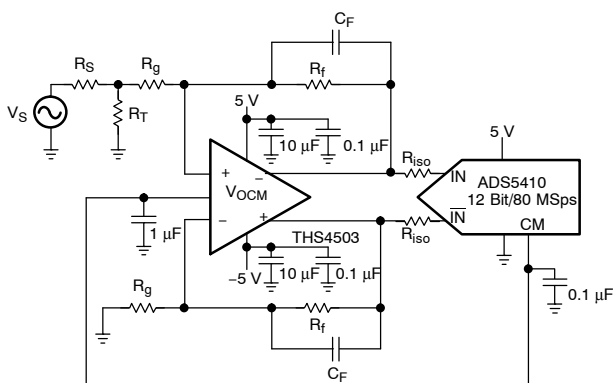
THS4503-EP

SGLS291A – APRIL 2005 – JANUARY 2012

- Decouple the V_{OCM} pin to eliminate the antenna effect. V_{OCM} is a high-impedance node that can act as an antenna. A large decoupling capacitor on this node eliminates this problem.
- Be cognizant of the input common-mode range. If the input signal is referenced around the negative power supply rail (e.g., around ground on a single 5-V supply), then the THS4500/1 accommodates the input signal. If the input signal is referenced around midrail, choose the THS4502/3 for the best operation.
- Packaging makes a difference at higher frequencies. If possible, choose the smaller, thermally enhanced MSOP package for the best performance. As a rule, lower junction temperatures provide better performance. If possible, use a thermally enhanced package, even if the power dissipation is relatively small compared to the maximum power dissipation rating to achieve the best results.
- Comprehend the effect of the load impedance seen by the fully differential amplifier when performing system-level intercept point calculations. Lighter loads (such as those presented by an ADC) allow smaller intercept points to support the same level of intermodulation distortion performance.

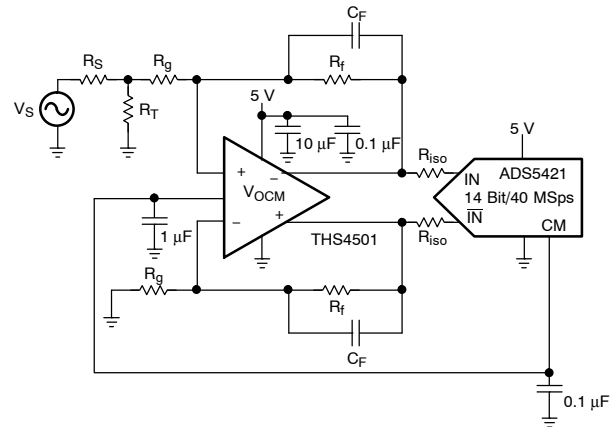
EXAMPLE ANALOG-TO-DIGITAL CONVERTER DRIVER CIRCUITS

The THS4500 family of devices is designed to drive high-performance ADCs with extremely high linearity, allowing for the maximum effective number of bits at the output of the data converter. Two representative circuits shown below highlight single-supply operation and split supply operation. Specific feedback resistor, gain resistor, and feedback capacitor values are not specified, as their values depend on the frequency of interest. Information on calculating these values can be found in the applications material above.



Using the THS4503 With the ADS5410

Figure 98

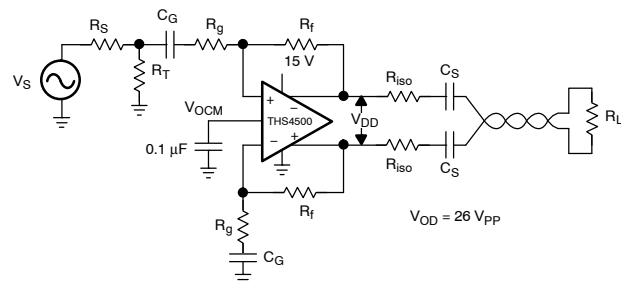


Using the THS4501 With the ADS5421

Figure 99

FULLY DIFFERENTIAL LINE DRIVERS

The THS4500 family of amplifiers can be used as high-frequency, high-swing differential line drivers. Their high power supply voltage rating (16.5 V absolute maximum) allows operation on a single 12-V or a single 15-V supply. The high supply voltage, coupled with the ability to provide differential outputs enables the ability to drive 26 V_{PP} into reasonably heavy loads (250 Ω or greater). The circuit in Figure 100 illustrates the THS4500 family of devices used as high speed line drivers. For line driver applications, close attention must be paid to thermal design constraints due to the typically high level of power dissipation.

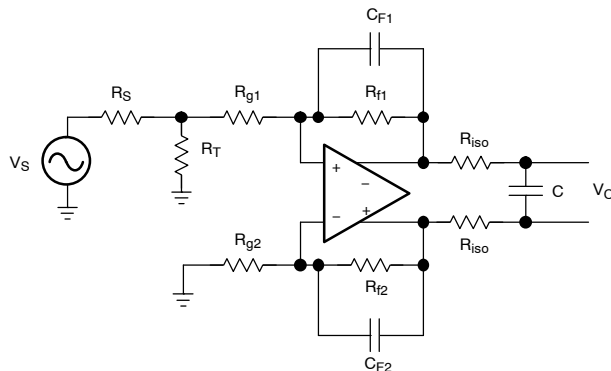


Fully Differential Line Driver With High Output Swing

Figure 100

FILTERING WITH FULLY DIFFERENTIAL AMPLIFIERS

Similar to their single-ended counterparts, fully differential amplifiers have the ability to couple filtering functionality with voltage gain. Numerous filter topologies can be based on fully differential amplifiers. Several of these are outlined in *A Differential Circuit Collection*, (SLOA064) referenced at the end of this data sheet. The circuit below depicts a simple two-pole low-pass filter applicable to many different types of systems. The first pole is set by the resistors and capacitors in the feedback paths, and the second pole is set by the isolation resistors and the capacitor across the outputs of the isolation resistors.



A Two-Pole, Low-Pass Filter Design Using a Fully Differential Amplifier With Poles Located at:
 $P1 = (2\pi R_f C_f)^{-1}$ in Hz and $P2 = (4\pi R_{iso} C)^{-1}$ in Hz

Figure 101

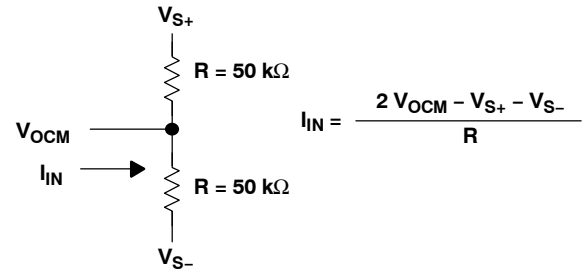
Often times, filters like these are used to eliminate broadband noise and out-of-band distortion products in signal acquisition systems. It should be noted that the increased load placed on the output of the amplifier by the second low-pass filter has a detrimental effect on the distortion performance. The preferred method of filtering is using the feedback network, as the typically smaller capacitances required at these points in the circuit do not load the amplifier nearly as heavily in the pass-band.

SETTING THE OUTPUT COMMON-MODE VOLTAGE WITH THE V_{OCM} INPUT

The output common-mode voltage pin provides a critical function to the fully differential amplifier; it accepts an input voltage and reproduces that input voltage as the output common-mode voltage. In other words, the V_{OCM} input provides the ability to level-shift the outputs to any voltage inside the output voltage swing of the amplifier.

A description of the input circuitry of the V_{OCM} pin is shown below to facilitate an easier understanding of the V_{OCM} interface requirements. The V_{OCM} pin has two 50-k Ω resistors between the power supply rails to set the default output common-mode voltage to midrail. A voltage

applied to the V_{OCM} pin alters the output common-mode voltage as long as the source has the ability to provide enough current to overdrive the two 50-k Ω resistors. This phenomenon is depicted in the V_{OCM} equivalent circuit diagram. The table contains some representative examples to aid in determining the current drive requirement for the V_{OCM} voltage source. This parameter is especially important when using the reference voltage of an analog-to-digital converter to drive V_{OCM} . Output current drive capabilities differ from part to part, so a voltage buffer may be necessary in some applications.



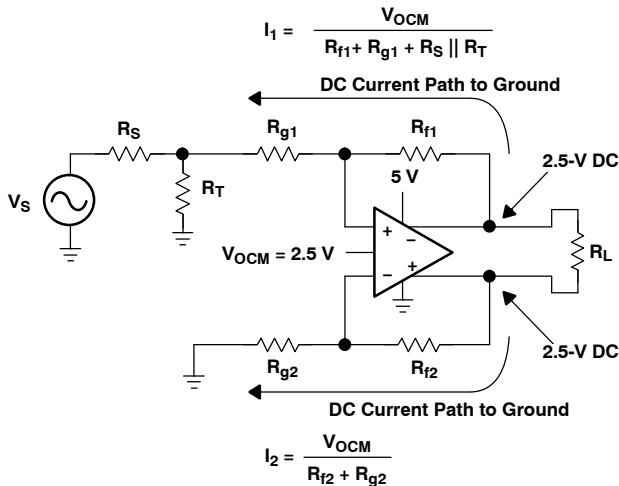
Equivalent Input Circuit for V_{OCM}
Figure 102

By design, the input signal applied to the V_{OCM} pin propagates to the outputs as a common-mode signal. As shown in the equivalent circuit diagram, the V_{OCM} input has a high impedance associated with it, dictated by the two 50-k Ω resistors. While the high impedance allows for relaxed drive requirements, it also allows the pin and any associated printed-circuit board traces to act as an antenna. For this reason, a decoupling capacitor is recommended on this node for the sole purpose of filtering any high frequency noise that could couple into the signal path through the V_{OCM} circuitry. A 0.1- μ F or 1- μ F capacitance is a reasonable value for eliminating a great deal of broadband interference, but additional, tuned decoupling capacitors should be considered if a specific source of electromagnetic or radio frequency interference is present elsewhere in the system. Information on the ac performance (bandwidth, slew rate) of the V_{OCM} circuitry is included in the specification table and graph section.

Since the V_{OCM} pin provides the ability to set an output common-mode voltage, the ability for increased power dissipation exists. While this does not pose a performance problem for the amplifier, it can cause additional power dissipation of which the system designer should be aware. The circuit shown in Figure 103 demonstrates an example of this phenomenon. For a device operating on a single 5-V supply with an input signal referenced around ground and an output common-mode voltage of 2.5 V, a dc potential exists between the outputs and the inputs of the device. The amplifier sources current into the feedback network in order to provide the circuit with the proper operating point. While there are no serious effects on the circuit performance, the extra power dissipation may need to be included in the system's power budget.

THS4503-EP

SGLS291A – APRIL 2005 – JANUARY 2012



Depiction of DC Power Dissipation Caused By Output Level-Shifting in a DC-Coupled Circuit

Figure 103

SAVING POWER WITH POWER-DOWN FUNCTIONALITY

The THS4500 family of fully differential amplifiers contains devices that come with and without the power-down option. Even-numbered devices have power-down capability, which is described in detail here.

The power-down pin of the amplifiers defaults to the positive supply voltage in the absence of an applied voltage (i.e. an internal pullup resistor is present), putting the amplifier in the *power-on* mode of operation. To turn off the amplifier in an effort to conserve power, the power-down pin can be driven towards the negative rail. The threshold voltages for power-on and power-down are relative to the supply rails and given in the specification tables. Above the *enable threshold voltage*, the device is on. Below the *disable threshold voltage*, the device is off. Behavior in between these threshold voltages is not specified.

Note that this power-down functionality is just that; the amplifier consumes less power in power-down mode. The power-down mode is not intended to provide a high-impedance output. In other words, the power-down functionality is not intended to allow use as a 3-state bus driver. When in power-down mode, the impedance looking back into the output of the amplifier is dominated by the feedback and gain setting resistors.

The time delays associated with turning the device on and off are specified as the time it takes for the amplifier to reach 50% of the nominal quiescent current. The time delays are on the order of microseconds because the amplifier moves in and out of the linear mode of operation in these transitions.

LINEARITY: DEFINITIONS, TERMINOLOGY, CIRCUIT TECHNIQUES, AND DESIGN TRADEOFFS

The THS4500 family of devices features unprecedented distortion performance for monolithic fully differential amplifiers. This section focuses on the fundamentals of distortion, circuit techniques for reducing nonlinearity, and methods for equating distortion of fully differential amplifiers to desired linearity specifications in RF receiver chains.

Amplifiers are generally thought of as *linear* devices. In other words, the output of an amplifier is a linearly scaled version of the input signal applied to it. In reality, however, amplifier transfer functions are nonlinear. Minimizing amplifier nonlinearity is a primary design goal in many applications.

Intercept points are specifications that have long been used as key design criteria in the RF communications world as a metric for the intermodulation distortion performance of a device in the signal chain (e.g., amplifiers, mixers, etc.). Use of the intercept point, rather than strictly the intermodulation distortion, allows for simpler system-level calculations. Intercept points, like noise figures, can be easily cascaded back and forth through a signal chain to determine the overall receiver chain's intermodulation distortion performance. The relationship between intermodulation distortion and intercept point is depicted in Figure 104 and Figure 105.

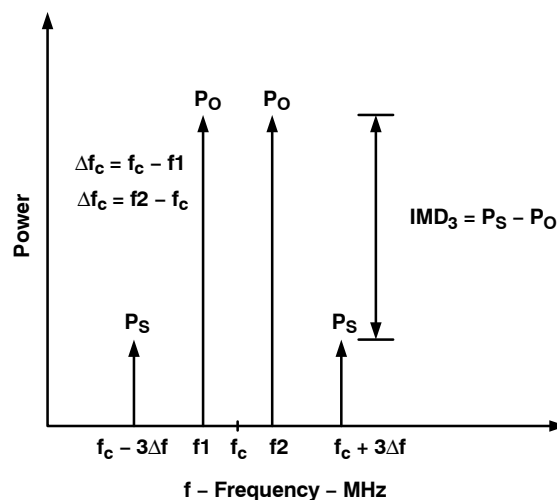


Figure 104

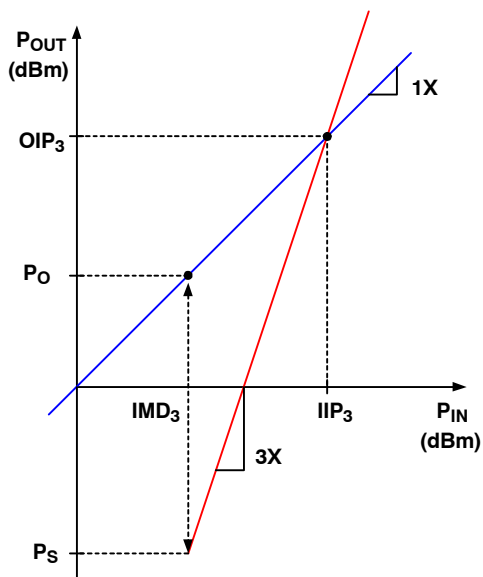


Figure 105

Due to the intercept point's ease of use in system level calculations for receiver chains, it has become the specification of choice for guiding distortion-related design decisions. Traditionally, these systems use primarily class-A, single-ended RF amplifiers as gain blocks. These RF amplifiers are typically designed to operate in a 50-Ω environment, just like the rest of the receiver chain. Since intercept points are given in dBm, this implies an associated impedance (50 Ω).

However, with a fully differential amplifier, the output does not require termination as an RF amplifier would. Because closed-loop amplifiers deliver signals to their outputs regardless of the impedance present, it is important to comprehend this when evaluating the intercept point of a fully differential amplifier. The THS4500 series of devices yields optimum distortion performance when loaded with 200 Ω to 1 kΩ, similar to the input impedance of an analog-to-digital converter over its input frequency band. As a result, terminating the input of the ADC to 50 Ω can actually be detrimental to system performance.

This discontinuity between open-loop, class-A amplifiers and closed-loop, class-AB amplifiers becomes apparent when comparing the intercept points of the two types of devices. Equation 10 gives the definition of an intercept point, relative to the intermodulation distortion.

$$OIP_3 = P_O + \left(\frac{IMD_3}{2} \right) \text{ where} \quad (10)$$

$$P_O = 10 \log \left(\frac{V_{Pdiff}^2}{2R_L \times 0.001} \right) \quad (11)$$

NOTE: P_O is the output power of a single tone, R_L is the differential load resistance, and V_{Pdiff} is the differential peak voltage for a single tone.

As can be seen in the equation, when a higher impedance is used, the same level of intermodulation distortion performance results in a lower intercept point. Therefore, it is important to comprehend the impedance seen by the output of the fully differential amplifier when selecting a minimum intercept point. The graphic below shows the relationship between the strict definition of an intercept point with a normalized, or equivalent, intercept point for the THS4503.

THIRD-ORDER OUTPUT INTERCEPT POINT
VS
FREQUENCY

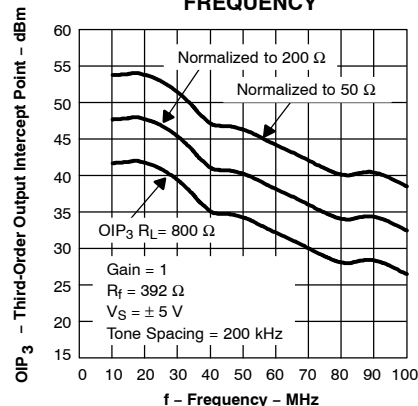


Figure 106

Comparing specifications between different device types becomes easier when a common impedance level is assumed. For this reason, the intercept points on the THS4500 family of devices are reported normalized to a 50-Ω load impedance.

AN ANALYSIS OF NOISE IN FULLY DIFFERENTIAL AMPLIFIERS

Noise analysis in fully differential amplifiers is analogous to noise analysis in single-ended amplifiers. The same concepts apply. Below, a generic circuit diagram consisting of a voltage source, a termination resistor, two gain setting resistors, two feedback resistors, and a fully differential amplifier is shown, including all the relevant noise sources. From this circuit, the noise factor (F) and noise figure (NF) are calculated. The figures indicate the appropriate scaling factor for each of the noise sources in two different cases. The first case includes the termination resistor, and the second, simplified case assumes that the voltage source is properly terminated by the gain-setting resistors. With these scaling factors, the amplifier's input noise power (N_A) can be calculated by summing each individual noise source with its scaling factor. The noise delivered to the amplifier by the source (N_i) and input noise power are used to calculate the noise factor and noise figure as shown in equations 23 through 27.

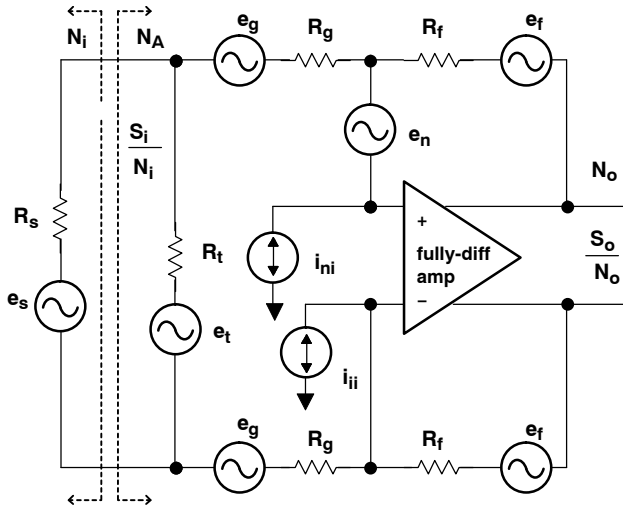


Figure 107. Noise Sources in a Fully Differential Amplifier Circuit

N_A : Fully Differential Amplifier

Noise Source

Scale Factor

$$(e_{ni})^2 \left[\frac{R_g}{R_f} + \frac{R_g}{R_g + \frac{R_s R_t}{2(R_s + R_t)}} \right]^2 \quad (12)$$

$$(i_{ni})^2 R_g^2 \quad (13)$$

$$(i_{ii})^2 R_g^2 \quad (14)$$

$$4kTR_t \left[\frac{\frac{2R_s R_g}{R_s + 2R_g}}{R_t + \frac{2R_s R_g}{R_s + 2R_g}} \right]^2 \quad (15)$$

$$4kTR_f 2 \times \left(\frac{R_g}{R_f} \right)^2 \quad (16)$$

$$4kTR_g 2 \times \left[\frac{R_g}{R_g + \frac{R_s R_t}{2(R_s + R_t)}} \right]^2 \quad (17)$$

Figure 108. Scaling Factors for Individual Noise Sources Assuming a Finite Value Termination Resistor

N_A : Fully Differential Amplifier; termination = $2R_g$

Noise Source

Scale Factor

$$(e_{ni})^2 \left[\frac{R_g}{R_f} + \frac{R_g}{R_g + \frac{R_s}{2}} \right]^2 \quad (18)$$

$$(i_{ni})^2 R_g^2 \quad (19)$$

$$(i_{ii})^2 R_g^2 \quad (20)$$

$$4kTR_f 2 \times \left(\frac{R_g}{R_f} \right)^2 \quad (21)$$

$$4kTR_g 2 \times \left[\frac{R_g}{R_g + \frac{R_s}{2}} \right]^2 \quad (22)$$

Figure 109. Scaling Factors for Individual Noise Sources Assuming No Termination Resistance is Used (e.g., R_T is open)

$$N_i = 4kTR_s \left[\frac{\frac{2R_t R_g}{R_t + 2R_g}}{R_s + \frac{2R_t R_g}{R_t + 2R_g}} \right]^2 \quad (23)$$

Figure 110. Input Noise With a Termination Resistor

$$N_i = 4kTR_s \left(\frac{2R_g}{R_s + 2R_g} \right)^2 \quad (24)$$

Figure 111. Input Noise Assuming No Termination Resistor

Noise Factor and Noise Figure Calculations

$$N_A = \Sigma(\text{Noise Source} \times \text{Scale Factor}) \quad (25)$$

$$F = 1 + \frac{N_A}{N_i} \quad (26)$$

$$NF = 10 \log (F) \quad (27)$$

PRINTED-CIRCUIT BOARD LAYOUT TECHNIQUES FOR OPTIMAL PERFORMANCE

Achieving optimum performance with high frequency amplifier-like devices in the THS4500 family requires careful attention to board layout parasitic and external component types.

Recommendations that optimize performance include:

- Minimize parasitic capacitance to any ac ground for all of the signal I/O pins. Parasitic capacitance on the output and input pins can cause instability. To reduce unwanted capacitance, a window around the signal I/O pins should be opened in all of the ground and power planes around those pins. Otherwise, ground and power planes should be unbroken elsewhere on the board.
- Minimize the distance ($< 0.25''$) from the power supply pins to high frequency 0.1- μF decoupling capacitors. At the device pins, the ground and power plane layout should not be in close proximity to the signal I/O pins. Avoid narrow power and ground traces to minimize inductance between the pins and the decoupling capacitors. The power supply connections should always be decoupled with these capacitors. Larger (6.8 μF or more) tantalum decoupling capacitors, effective at lower frequency, should also be used on the main supply pins. These may be placed somewhat farther from the device and may be shared among several devices in the same area of the PC board. The primary goal is to minimize the impedance seen in the differential-current return paths.
- Careful selection and placement of external components preserve the high frequency performance of the THS4500 family. Resistors should be a low reactance type. Surface-mount resistors work best and allow a tighter overall layout. Metal-film and carbon composition, axially-leaded resistors can also provide good high frequency performance. Again, keep their leads and PC board trace length as short as possible. Never use wirewound type resistors in a high frequency application. Since the output pin and inverting input pins are the most sensitive to parasitic capacitance, always position the feedback and series output resistors, if any, as close as possible to the inverting input pins and output pins. Other network components, such as input termination resistors, should be placed close to the gain-setting resistors. Even with a low parasitic capacitance shunting the external resistors, excessively high resistor values can create significant time constants that can degrade performance. Good axial metal-film or surface-mount resistors have approximately 0.2 pF in shunt with the resistor. For resistor values $> 2 \text{ k}\Omega$, this parasitic capacitance can add a pole and/or a zero

below 400 MHz that can effect circuit operation. Keep resistor values as low as possible, consistent with load driving considerations.

- Connections to other wideband devices on the board may be made with short direct traces or through onboard transmission lines. For short connections, consider the trace and the input to the next device as a lumped capacitive load. Relatively wide traces (50 mils to 100 mils) should be used, preferably with ground and power planes opened up around them. Estimate the total capacitive load and determine if isolation resistors on the outputs are necessary. Low parasitic capacitive loads ($< 4 \text{ pF}$) may not need an R_S since the THS4500 family is nominally compensated to operate with a 2-pF parasitic load. Higher parasitic capacitive loads without an R_S are allowed as the signal gain increases (increasing the unloaded phase margin). If a long trace is required, and the 6-dB signal loss intrinsic to a doubly-terminated transmission line is acceptable, implement a matched impedance transmission line using microstrip or stripline techniques (consult an ECL design handbook for microstrip and stripline layout techniques).

A 50- Ω environment is normally not necessary onboard, and in fact, a higher impedance environment improves distortion as shown in the distortion versus load plots. With a characteristic board trace impedance defined based on board material and trace dimensions, a matching series resistor into the trace from the output of the THS4500 family is used as well as a terminating shunt resistor at the input of the destination device.

Remember also that the terminating impedance is the parallel combination of the shunt resistor and the input impedance of the destination device: this total effective impedance should be set to match the trace impedance. If the 6-dB attenuation of a doubly terminated transmission line is unacceptable, a long trace can be series-terminated at the source end only. Treat the trace as a capacitive load in this case. This does not preserve signal integrity as well as a doubly-terminated line. If the input impedance of the destination device is low, there is some signal attenuation due to the voltage divider formed by the series output into the terminating impedance.

- Socketing a high speed part like the THS4500 family is not recommended. The additional lead length and pin-to-pin capacitance introduced by the socket can create an extremely troublesome parasitic network which can make it almost impossible to achieve a smooth, stable frequency response. Best results are obtained by soldering the THS4500 family parts directly onto the board.

PowerPAD DESIGN CONSIDERATIONS

The THS4500 family is available in a thermally-enhanced PowerPAD family of packages. These packages are constructed using a downset leadframe upon which the die is mounted [see Figure 112(a) and Figure 112(b)]. This arrangement results in the lead frame being exposed as a thermal pad on the underside of the package [see Figure 112(c)]. Because this thermal pad has direct thermal contact with the die, excellent thermal performance can be achieved by providing a good thermal path away from the thermal pad.

The PowerPAD package allows for both assembly and thermal management in one manufacturing operation. During the surface-mount solder operation (when the leads are being soldered), the thermal pad can also be soldered to a copper area underneath the package. Through the use of thermal paths within this copper area, heat can be conducted away from the package into either a ground plane or other heat dissipating device.

The PowerPAD package represents a breakthrough in combining the small area and ease of assembly of surface mount with the, heretofore, awkward mechanical methods of heatsinking.

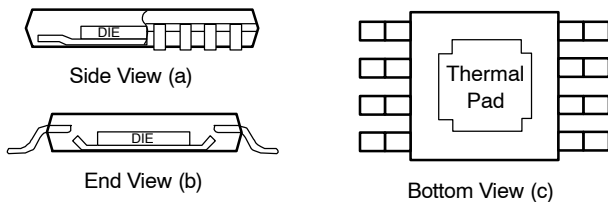


Figure 112. Views of Thermally Enhanced Package

Although there are many ways to properly heatsink the PowerPAD package, the following steps illustrate the recommended approach.

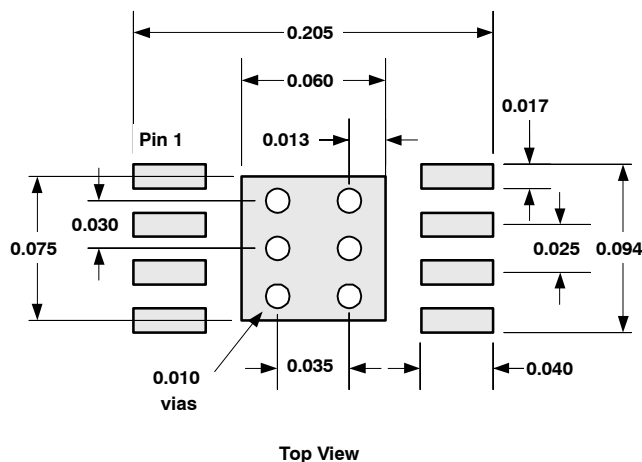


Figure 113. PowerPAD PCB Etch and Via Pattern

PowerPAD PCB LAYOUT CONSIDERATIONS

1. Prepare the PCB with a top side etch pattern as shown in Figure 113. There should be etch for the leads as well as etch for the thermal pad.
2. Place five holes in the area of the thermal pad. These holes should be 13 mils in diameter. Keep the holes small so that solder wicking through the holes is not a problem during reflow.
3. Additional vias may be placed anywhere along the thermal plane outside of the thermal pad area. This helps dissipate the heat generated by the THS4500 family IC. These additional vias may be larger than the 13-mil diameter vias directly under the thermal pad. They can be larger because they are not in the thermal pad area to be soldered so that wicking is not a problem.
4. Connect all holes to the internal ground plane.
5. When connecting these holes to the ground plane, **do not** use the typical web or spoke via connection methodology. Web connections have a high thermal resistance connection that is useful for slowing the heat transfer during soldering operations. This makes the soldering of vias that have plane connections easier. In this application, however, low thermal resistance is desired for the most efficient heat transfer. Therefore, the holes under the THS4500 family PowerPAD package should make their connection to the internal ground plane with a complete connection around the entire circumference of the plated-through hole.
6. The top-side solder mask should leave the terminals of the package and the thermal pad area with its five holes exposed. The bottom-side solder mask should cover the five holes of the thermal pad area. This prevents solder from being pulled away from the thermal pad area during the reflow process.
7. Apply solder paste to the exposed thermal pad area and all of the IC terminals.
8. With these preparatory steps in place, the IC is simply placed in position and run through the solder reflow operation as any standard surface-mount component. This results in a part that is properly installed.

POWER DISSIPATION AND THERMAL CONSIDERATIONS

The THS4500 family of devices does not incorporate automatic thermal shutoff protection, so the designer must take care to ensure that the design does not violate the absolute maximum junction temperature of the device. Failure may result if the absolute maximum junction temperature of 150°C is exceeded. For best performance, design for a maximum junction temperature of 125°C. Between 125°C and 150°C, damage does not occur, but the performance of the amplifier begins to degrade.

The thermal characteristics of the device are dictated by the package and the PC board. Maximum power dissipation for a given package can be calculated using the following formula.

$$P_{Dmax} = \frac{T_{max} - T_A}{\theta_{JA}} \quad (28)$$

Where:

P_{Dmax} is the maximum power dissipation in the amplifier (W).

T_{max} is the absolute maximum junction temperature ($^{\circ}\text{C}$).

T_A is the ambient temperature ($^{\circ}\text{C}$).

$\theta_{JA} = \theta_{JC} + \theta_{CA}$

θ_{JC} is the thermal coefficient from the silicon junctions to the case ($^{\circ}\text{C}/\text{W}$).

θ_{CA} is the thermal coefficient from the case to ambient air ($^{\circ}\text{C}/\text{W}$).

For systems where heat dissipation is more critical, the THS4500 family of devices is offered in an 8-pin MSOP with PowerPAD. The thermal coefficient for the MSOP PowerPAD package is substantially improved over the traditional SOIC. Maximum power dissipation levels are depicted in the graph for the two packages. The data for the DGN package assumes a board layout that follows the PowerPAD layout guidelines referenced above and detailed in the PowerPAD application notes in the *Additional Reference Material* section at the end of the data sheet.

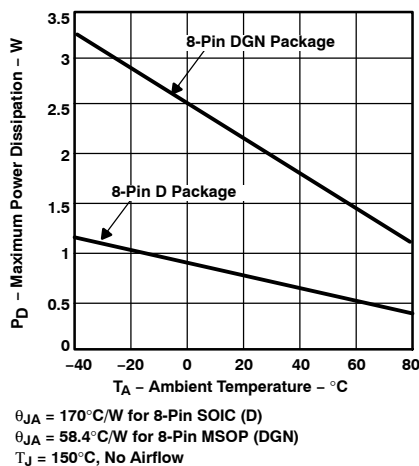
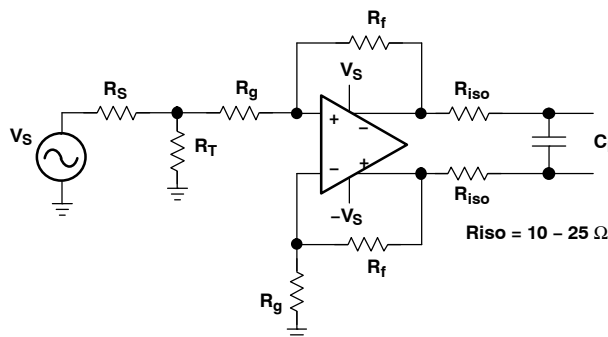


Figure 114. Maximum Power Dissipation vs Ambient Temperature

When determining whether or not the device satisfies the maximum power dissipation requirement, it is important to not only consider quiescent power dissipation, but also dynamic power dissipation. Often times, this is difficult to quantify because the signal pattern is inconsistent, but an estimate of the RMS power dissipation can provide visibility into a possible problem.

DRIVING CAPACITIVE LOADS

High-speed amplifiers are typically not well-suited for driving large capacitive loads. If necessary, however, the load capacitance should be isolated by two isolation resistors in series with the output. The requisite isolation resistor size depends on the value of the capacitance, but $10\ \Omega$ to $25\ \Omega$ is a good place to begin the optimization process. Larger isolation resistors decrease the amount of peaking in the frequency response induced by the capacitive load, but this comes at the expense of larger voltage drop across the resistors, increasing the output swing requirements of the system.



Use of Isolation Resistors With a Capacitive Load.

Figure 115

POWER SUPPLY DECOUPLING TECHNIQUES AND RECOMMENDATIONS

Power supply decoupling is a critical aspect of any high-performance amplifier design process. Careful decoupling provides higher quality ac performance (most notably improved distortion performance). The following guidelines ensure the highest level of performance.

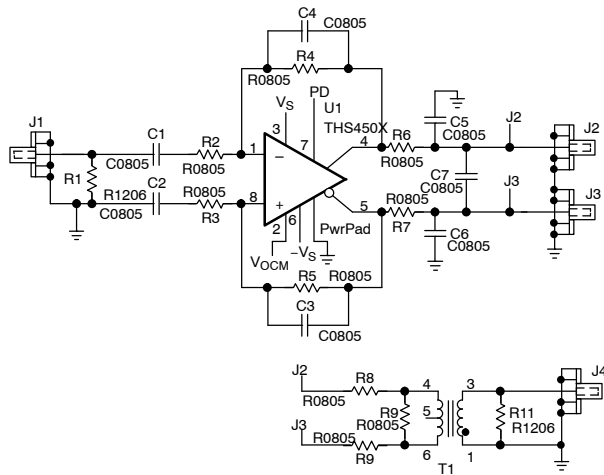
1. Place decoupling capacitors as close to the power supply inputs as possible, with the goal of minimizing the inductance of the path from ground to the power supply.
2. Placement priority should be as follows: smaller capacitors should be closer to the device.
3. Use of solid power and ground planes is recommended to reduce the inductance along power supply return current paths.
4. Recommended values for power supply decoupling include $10\text{-}\mu\text{F}$ and $0.1\text{-}\mu\text{F}$ capacitors for each supply. A 1000-pF capacitor can be used across the supplies as well for extremely high frequency return currents, but often is not required.

THS4503-EP

SGLS291A – APRIL 2005 – JANUARY 2012

EVALUATION FIXTURES, SPICE MODELS, AND APPLICATIONS SUPPORT

Texas Instruments is committed to providing its customers with the highest quality of applications support. To support this goal, an evaluation board has been developed for the THS4500 family of fully differential amplifiers. The evaluation board can be obtained by ordering through the Texas Instruments web site, www.ti.com, or through your local Texas Instruments sales representative. Schematic for the evaluation board is shown below with their default component values. Unpopulated footprints are shown to provide insight into design flexibility.



Simplified Schematic of the Evaluation Board. Power Supply Decoupling, V_{OCM} , and Power Down Circuitry Not Shown

Figure 116

Computer simulation of circuit performance using SPICE is often useful when analyzing the performance of analog circuits and systems. This is particularly true for video and RF amplifier circuits where parasitic capacitance and inductance can have a major effect on circuit performance. A SPICE model for the THS4500 family of devices is available through the Texas Instruments web site (www.ti.com). The PIC is also available for design assistance and detailed product information. These models do a good job of predicting small-signal ac and transient performance under a wide variety of operating conditions. They are not intended to model the distortion characteristics of the amplifier, nor do they attempt to distinguish between the package types in their small-signal ac performance. Detailed information about what is and is not modeled is contained in the model file itself.

ADDITIONAL REFERENCE MATERIAL

- *PowerPAD Made Easy*, application brief, Texas Instruments (SLMA004)
- *PowerPAD Thermally Enhanced Package*, technical brief, Texas Instruments (SLMA002)
- Karki, James. *Fully Differential Amplifiers*. application report, Texas Instruments (SLOA054D)
- Karki, James. *Fully Differential Amplifiers Applications: Line Termination, Driving High-Speed ADCs, and Differential Transmission Lines*. Texas Instruments Analog Applications Journal, February 2001
- Carter, Bruce. *A Differential Op-Amp Circuit Collection*. application report, Texas Instruments (SLOA064)
- Carter, Bruce. *Differential Op-Amp Single-Supply Design Technique*, application report, Texas Instruments (SLOA072)
- Karki, James. *Designing for Low Distortion with High-Speed Op Amps*. Texas Instruments Analog Applications Journal, July 2001

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish	MSL Peak Temp (3)	Op Temp (°C)	Top-Side Markings (4)	Samples
THS4503MDGNREP	ACTIVE	MSOP- PowerPAD	DGN	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 60	BLB	Samples
V62/05608-03YE	ACTIVE	MSOP- PowerPAD	DGN	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 60	BLB	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) Only one of markings shown within the brackets will appear on the physical device.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

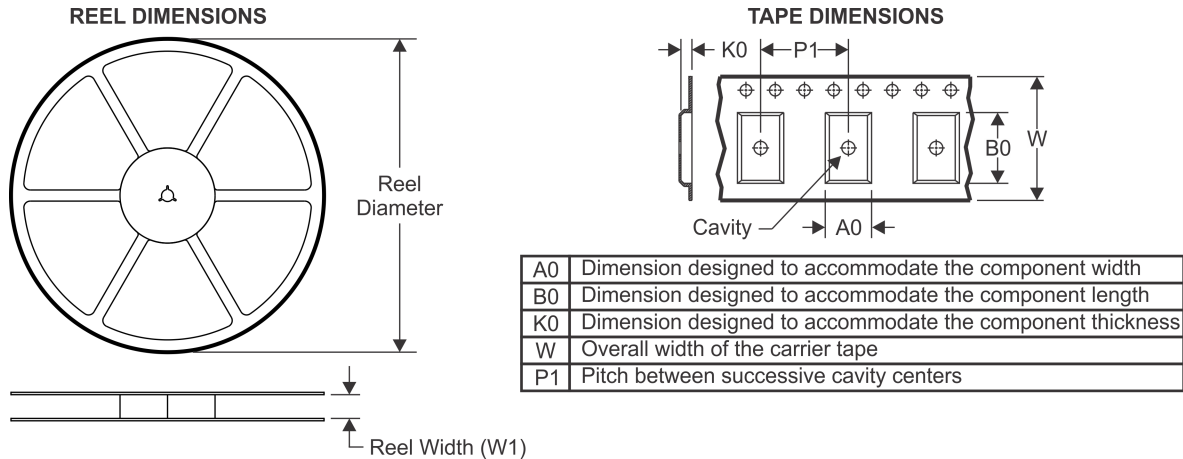
OTHER QUALIFIED VERSIONS OF THS4503-EP :

- Catalog: [THS4503](#)

NOTE: Qualified Version Definitions:

- Catalog - TI's standard catalog product

TAPE AND REEL INFORMATION



QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
THS4503MDGNREP	MSOP-Power PAD	DGN	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1

TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
THS4503MDGNREP	MSOP-PowerPAD	DGN	8	2500	358.0	335.0	35.0

DGN (S-PDSO-G8)

PowerPAD™ PLASTIC SMALL OUTLINE



- NOTES:
- A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Body dimensions do not include mold flash or protrusion.
 - D. This package is designed to be soldered to a thermal pad on the board. Refer to Technical Brief, PowerPad Thermally Enhanced Package, Texas Instruments Literature No. SLMA002 for information regarding recommended board layout. This document is available at www.ti.com <<http://www.ti.com>>.
 - E. See the additional figure in the Product Data Sheet for details regarding the exposed thermal pad features and dimensions.
 - F. Falls within JEDEC MO-187 variation AA-T

PowerPAD is a trademark of Texas Instruments.

DGN (S-PDSO-G8)

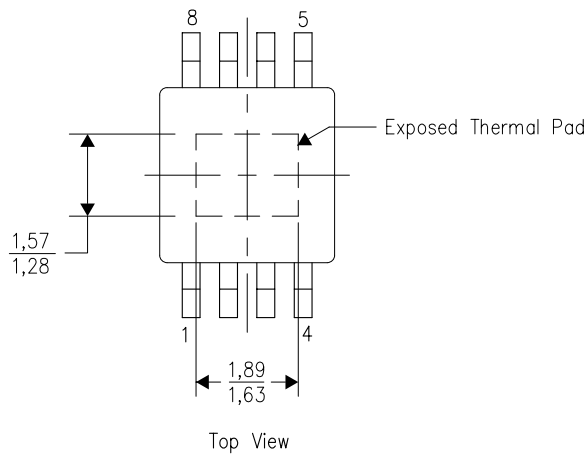
PowerPAD™ PLASTIC SMALL OUTLINE

THERMAL INFORMATION

This PowerPAD™ package incorporates an exposed thermal pad that is designed to be attached to a printed circuit board (PCB). The thermal pad must be soldered directly to the PCB. After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For additional information on the PowerPAD package and how to take advantage of its heat dissipating abilities, refer to Technical Brief, PowerPAD Thermally Enhanced Package, Texas Instruments Literature No. SLMA002 and Application Brief, PowerPAD Made Easy, Texas Instruments Literature No. SLMA004. Both documents are available at www.ti.com.

The exposed thermal pad dimensions for this package are shown in the following illustration.



Exposed Thermal Pad Dimensions

4206323-2/1 12/11

NOTE: All linear dimensions are in millimeters

PowerPAD is a trademark of Texas Instruments



- NOTES:
- A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
 - D. This package is designed to be soldered to a thermal pad on the board. Refer to Technical Brief, PowerPad Thermally Enhanced Package, Texas Instruments Literature No. SLMA002, SLMA004, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at www.ti.com <<http://www.ti.com>>.
 - E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.
 - F. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

PowerPAD is a trademark of Texas Instruments

IMPORTANT NOTICE

Texas Instruments Incorporated and its subsidiaries (TI) reserve the right to make corrections, enhancements, improvements and other changes to its semiconductor products and services per JESD46, latest issue, and to discontinue any product or service per JESD48, latest issue. Buyers should obtain the latest relevant information before placing orders and should verify that such information is current and complete. All semiconductor products (also referred to herein as "components") are sold subject to TI's terms and conditions of sale supplied at the time of order acknowledgment.

TI warrants performance of its components to the specifications applicable at the time of sale, in accordance with the warranty in TI's terms and conditions of sale of semiconductor products. Testing and other quality control techniques are used to the extent TI deems necessary to support this warranty. Except where mandated by applicable law, testing of all parameters of each component is not necessarily performed.

TI assumes no liability for applications assistance or the design of Buyers' products. Buyers are responsible for their products and applications using TI components. To minimize the risks associated with Buyers' products and applications, Buyers should provide adequate design and operating safeguards.

TI does not warrant or represent that any license, either express or implied, is granted under any patent right, copyright, mask work right, or other intellectual property right relating to any combination, machine, or process in which TI components or services are used. Information published by TI regarding third-party products or services does not constitute a license to use such products or services or a warranty or endorsement thereof. Use of such information may require a license from a third party under the patents or other intellectual property of the third party, or a license from TI under the patents or other intellectual property of TI.

Reproduction of significant portions of TI information in TI data books or data sheets is permissible only if reproduction is without alteration and is accompanied by all associated warranties, conditions, limitations, and notices. TI is not responsible or liable for such altered documentation. Information of third parties may be subject to additional restrictions.

Resale of TI components or services with statements different from or beyond the parameters stated by TI for that component or service voids all express and any implied warranties for the associated TI component or service and is an unfair and deceptive business practice. TI is not responsible or liable for any such statements.

Buyer acknowledges and agrees that it is solely responsible for compliance with all legal, regulatory and safety-related requirements concerning its products, and any use of TI components in its applications, notwithstanding any applications-related information or support that may be provided by TI. Buyer represents and agrees that it has all the necessary expertise to create and implement safeguards which anticipate dangerous consequences of failures, monitor failures and their consequences, lessen the likelihood of failures that might cause harm and take appropriate remedial actions. Buyer will fully indemnify TI and its representatives against any damages arising out of the use of any TI components in safety-critical applications.

In some cases, TI components may be promoted specifically to facilitate safety-related applications. With such components, TI's goal is to help enable customers to design and create their own end-product solutions that meet applicable functional safety standards and requirements. Nonetheless, such components are subject to these terms.

No TI components are authorized for use in FDA Class III (or similar life-critical medical equipment) unless authorized officers of the parties have executed a special agreement specifically governing such use.

Only those TI components which TI has specifically designated as military grade or "enhanced plastic" are designed and intended for use in military/aerospace applications or environments. Buyer acknowledges and agrees that any military or aerospace use of TI components which have **not** been so designated is solely at the Buyer's risk, and that Buyer is solely responsible for compliance with all legal and regulatory requirements in connection with such use.

TI has specifically designated certain components as meeting ISO/TS16949 requirements, mainly for automotive use. In any case of use of non-designated products, TI will not be responsible for any failure to meet ISO/TS16949.

Products

Audio	www.ti.com/audio
Amplifiers	amplifier.ti.com
Data Converters	dataconverter.ti.com
DLP® Products	www.dlp.com
DSP	dsp.ti.com
Clocks and Timers	www.ti.com/clocks
Interface	interface.ti.com
Logic	logic.ti.com
Power Mgmt	power.ti.com
Microcontrollers	microcontroller.ti.com
RFID	www.ti-rfid.com
OMAP Applications Processors	www.ti.com/omap
Wireless Connectivity	www.ti.com/wirelessconnectivity

Applications

Automotive and Transportation	www.ti.com/automotive
Communications and Telecom	www.ti.com/communications
Computers and Peripherals	www.ti.com/computers
Consumer Electronics	www.ti.com/consumer-apps
Energy and Lighting	www.ti.com/energy
Industrial	www.ti.com/industrial
Medical	www.ti.com/medical
Security	www.ti.com/security
Space, Avionics and Defense	www.ti.com/space-avionics-defense
Video and Imaging	www.ti.com/video

TI E2E Community

e2e.ti.com

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

[Texas Instruments:](#)

[THS4503MDGNREP](#) [V62/05608-03YE](#)